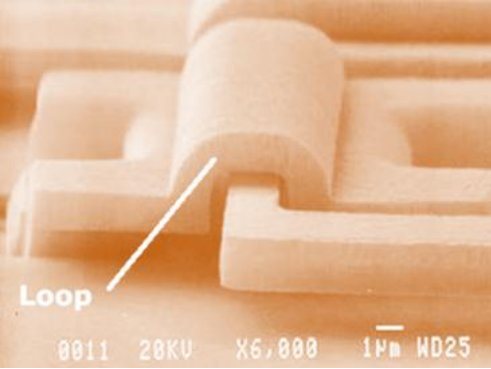
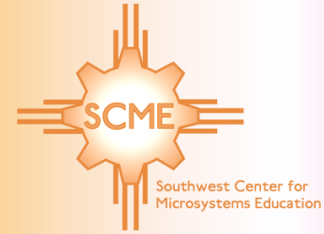


Statistical Process Control (SPC) For Technicians

Presented by
Southwest Center for
Microsystems Education
-SCME-
January 2013



Our Presenters

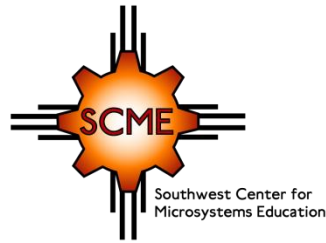


Barb Lopez
Research Engineer, University of
New Mexico and Instructional
Designer, SCME



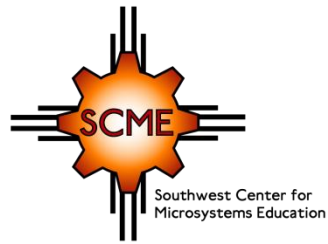
Mary Jane (MJ) Willis
Instructional Designer, SCME
and retired Chair for the
Manufacturing Technology
Program – Central New Mexico
Community College





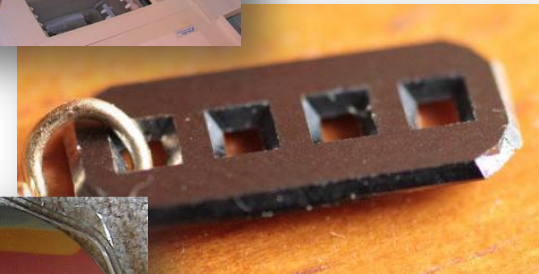
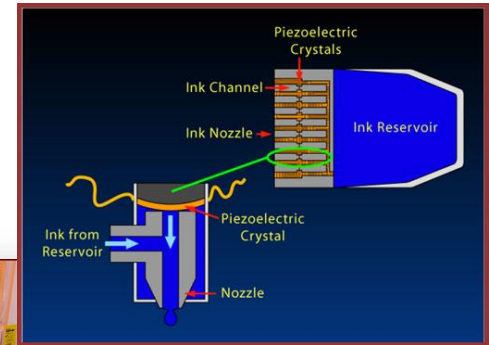
What will we cover today?

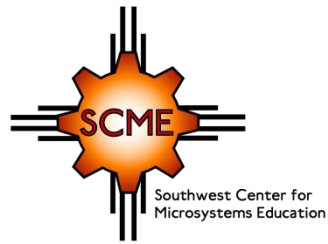
- What SCME can do for you
- Process variation and the need to identify special cause variation
- Statistical Process Control (SPC)
- Statistical tools necessary to employ SPC
- Normal distribution and how it is significant in \bar{X} -charts
- \bar{X} -charts and how to create them
- Interpreting Control Charts by applying the Shewhart rules



Educational Materials

- SCME Learning Modules
 - Informational Units / lessons
 - Supporting activities
 - Supporting assessments
- ~40 Modules in the areas of
 - Safety
 - Microsystems Introduction
 - Microsystems Applications
 - Bio MEMS
 - Microsystems Fabrication
- 11 Instructional Kits
- All are available @ scme-nm.org





Professional Development

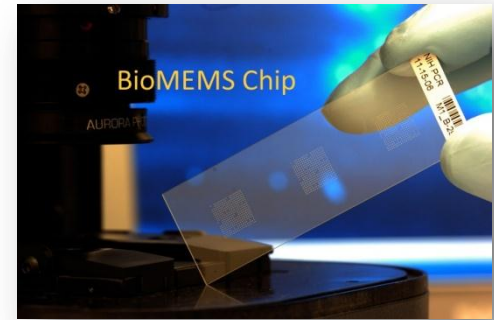
- 4 to 5-day workshops
- 2-day workshops
- 1-day workshop
- Conferences and conference workshops
- Create hubs at other colleges to teach our workshops
- Webinars
- SCME on YouTube (<https://www.youtube.com/user/scme2012>)



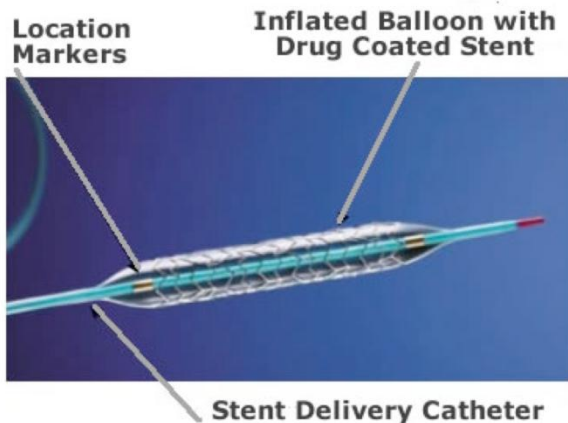
Why do we need (SPC) Statistical Process Control?



Quality Product



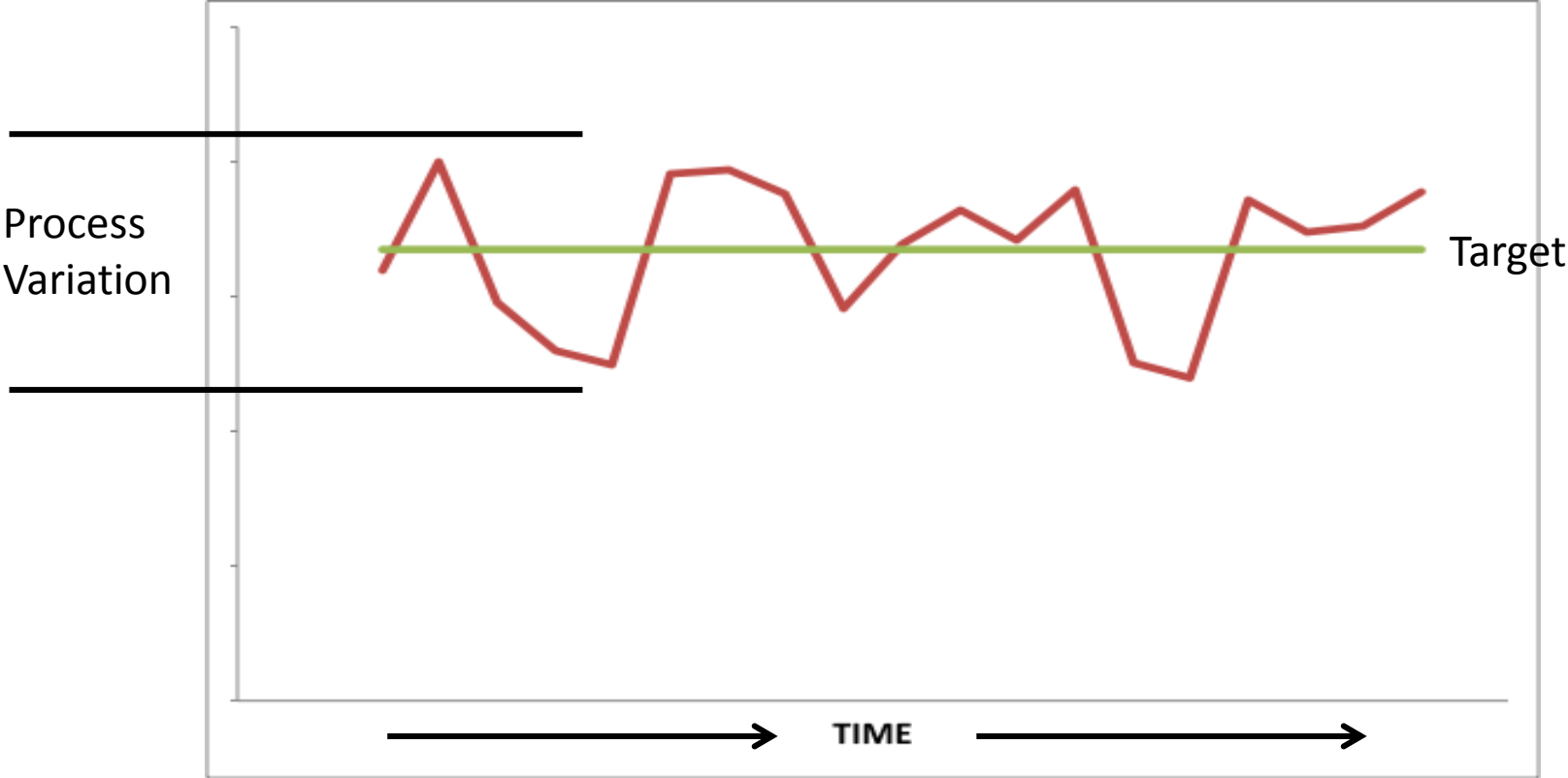
*Biochip slide for testing protein arrays
[Image courtesy of Argonne National Laboratories]*



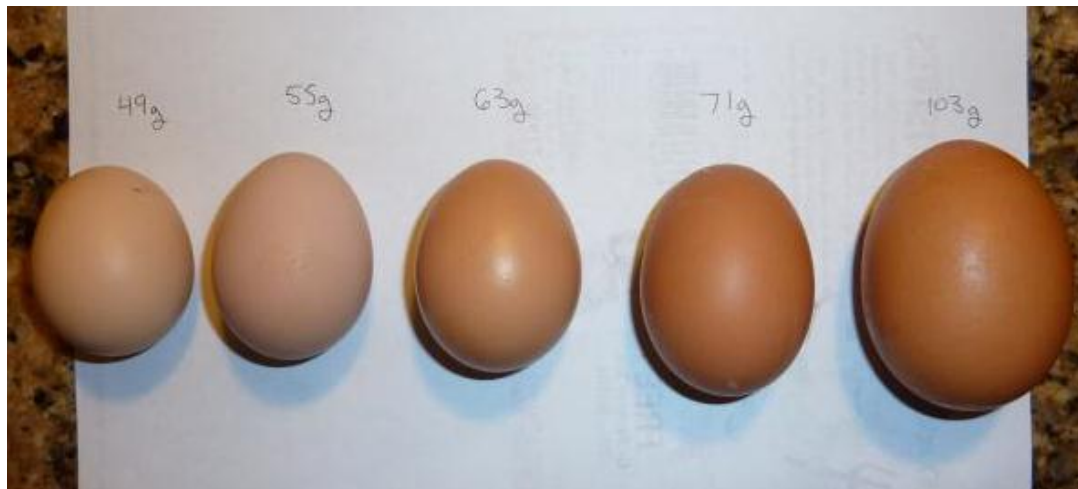
Drug-eluting Stent by Taxus [Image provided by the FDA]

Statistical Process Control (SPC)

SPC is about “control”.

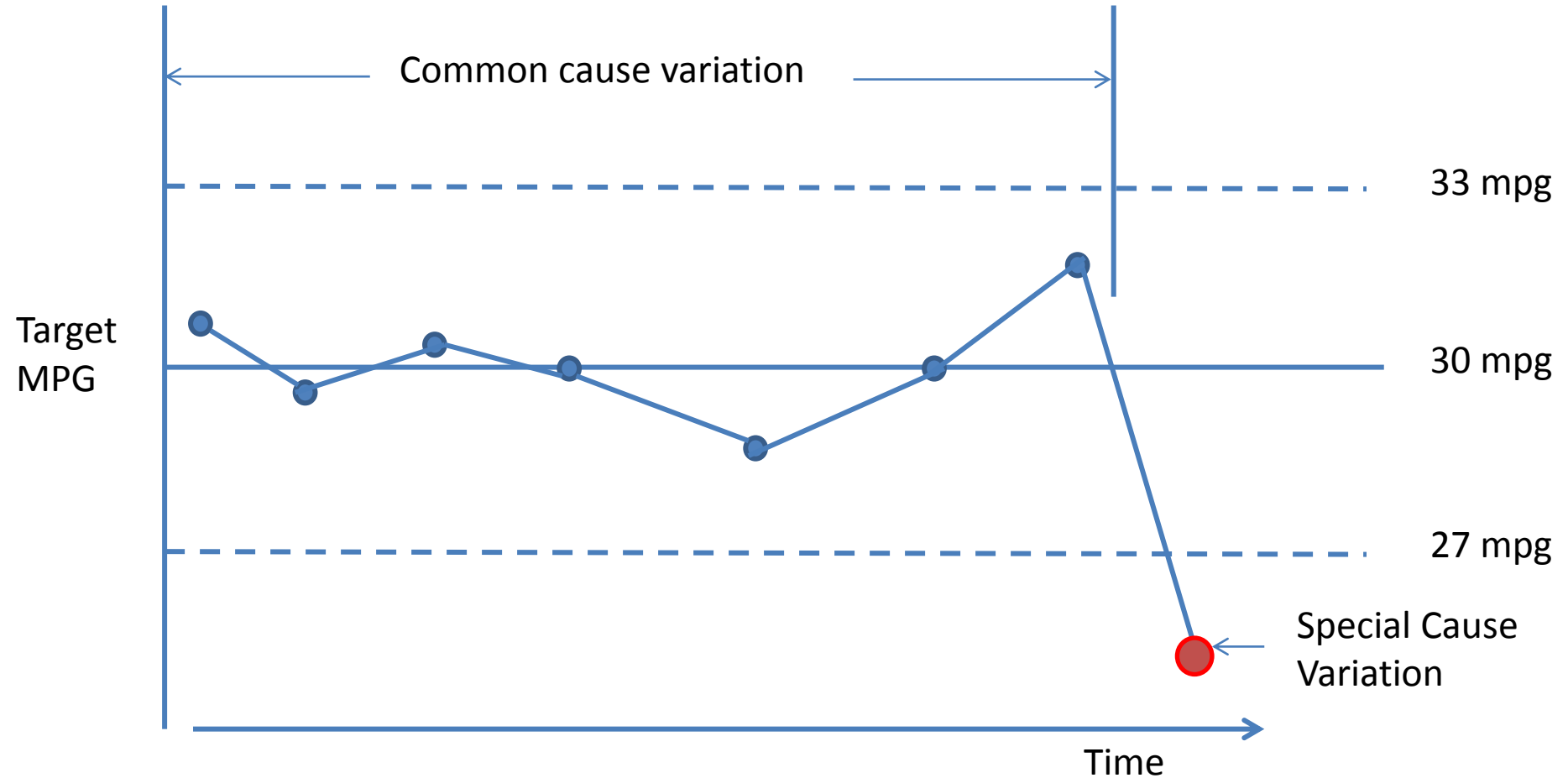


Inherent or Common Cause Variation



Special Cause Variation

Tracking Your Gas Mileage



Special Cause Variability

Process Steps:

1. Silicon Nitride Deposition
2. Lithography for chamber
3. Lithography for sensing circuit
4. Metal deposition for circuit
5. Metal Removal
6. Etch reference chamber



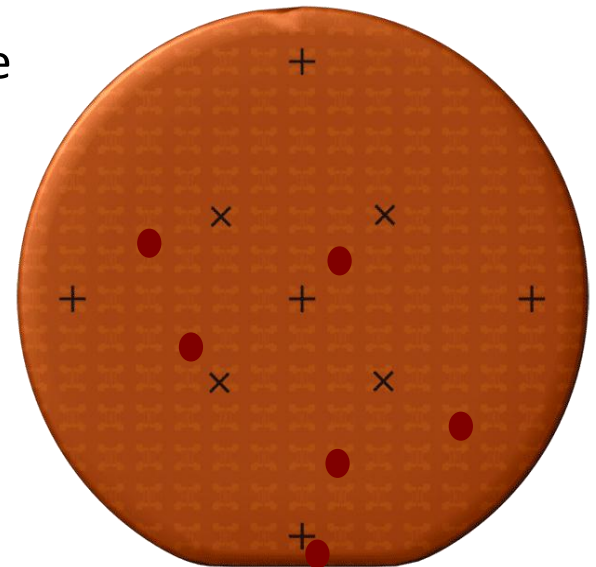
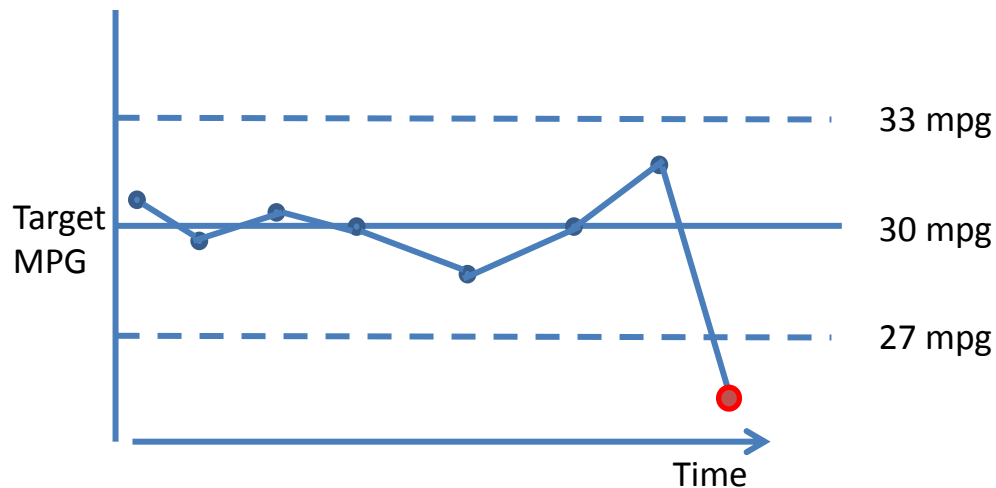
Diaphragm

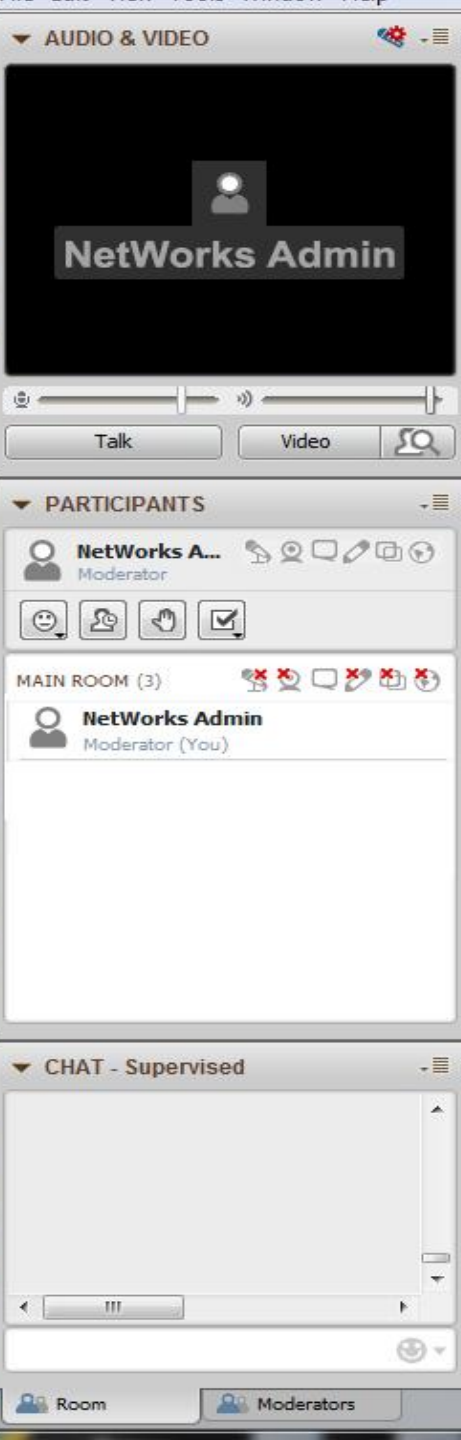
The image shows a micrograph of a device with a central diaphragm and surrounding electronic sensing circuit. The diaphragm is a thin, rectangular structure in the center, and the sensing circuit consists of various metal traces and pads around it. The labels 'Diaphragm' and 'Electronic Sensing circuit' are in yellow text with black outlines, and black lines point to the respective parts of the device.

**Electronic
Sensing
circuit**

Types of data

- Variable Data
 - Data Based upon measurements
 - Length, time, weight, temperature, pressure, film thickness
- Attribute Data
 - Data based upon counts (discrete)
 - Either there or not
 - Number of defects, acceptable or unacceptable

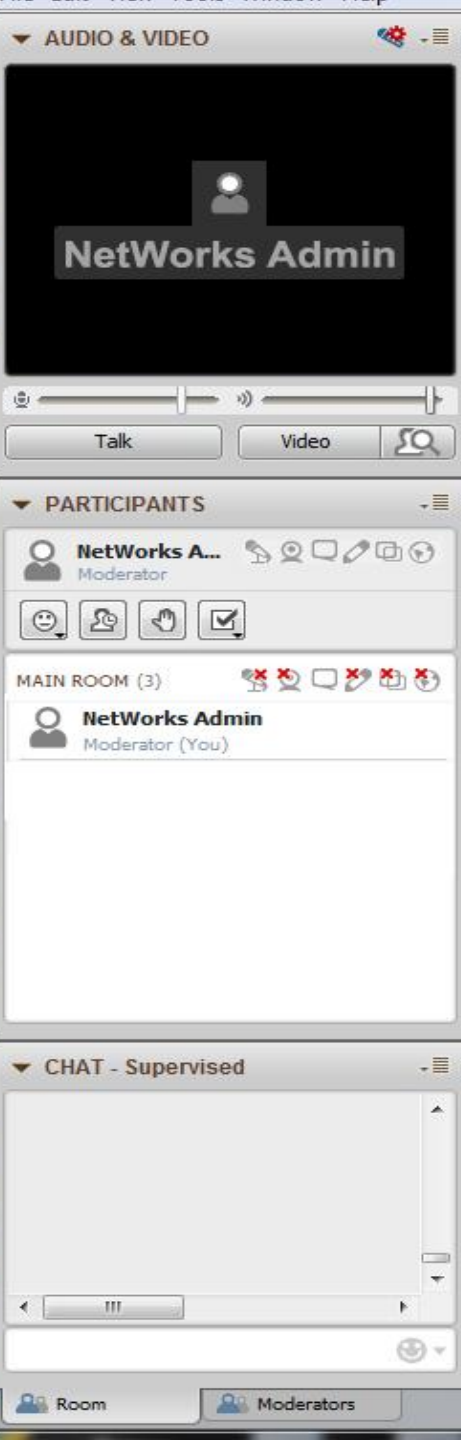




New Page Delete Page Fit Page Public Page 1

? Type questions in your chat window

Is the number of rejected wafers due to contamination variable data or attribute data?



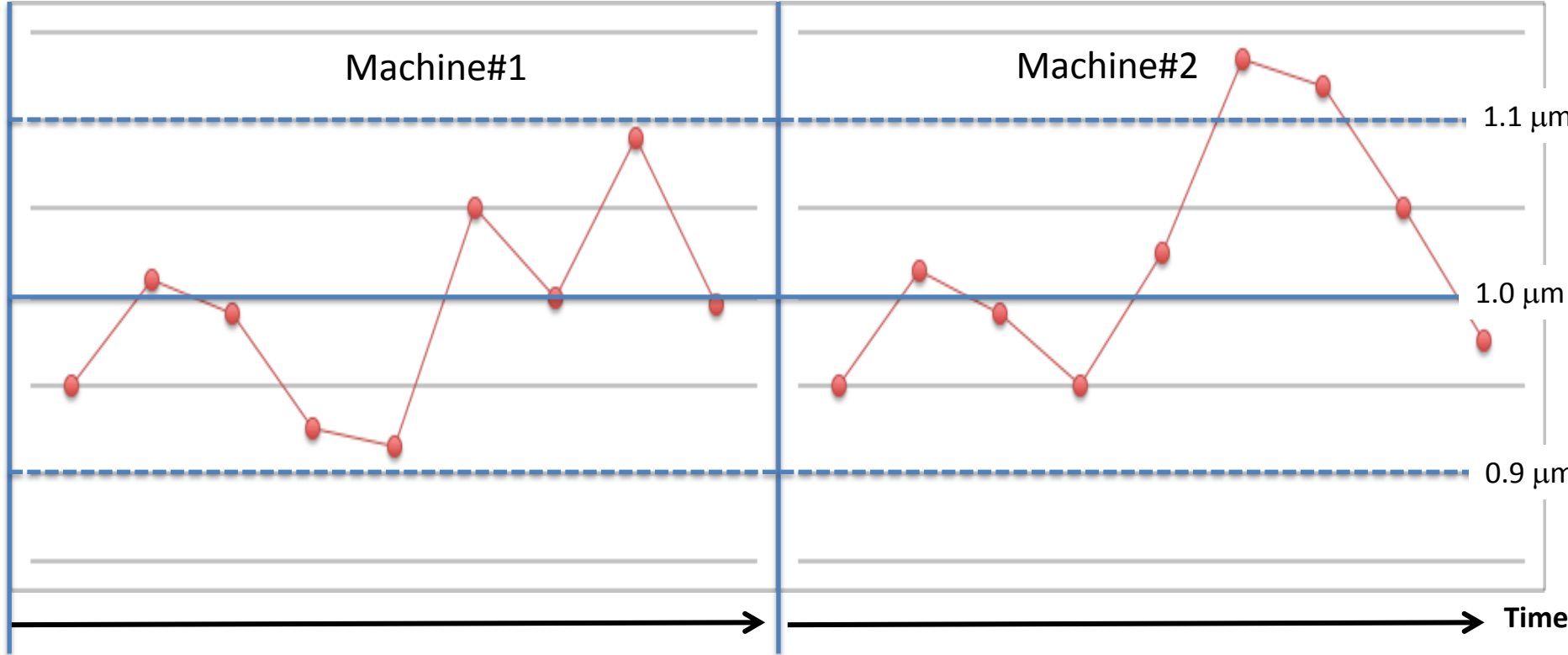
New Page Delete Page Fit Page Public Page 1

? Type questions in your chat window

Write an example of variable data in the chat box.

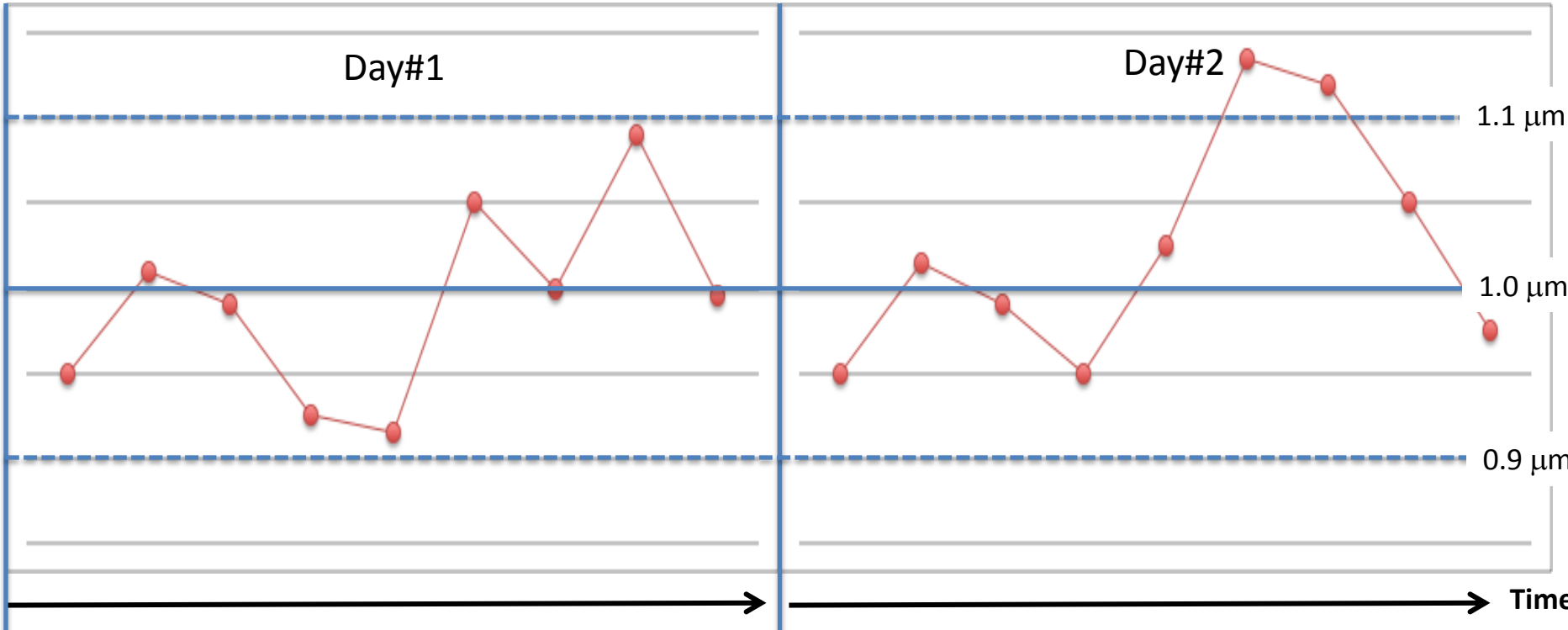
Variability

Photoresist Thickness



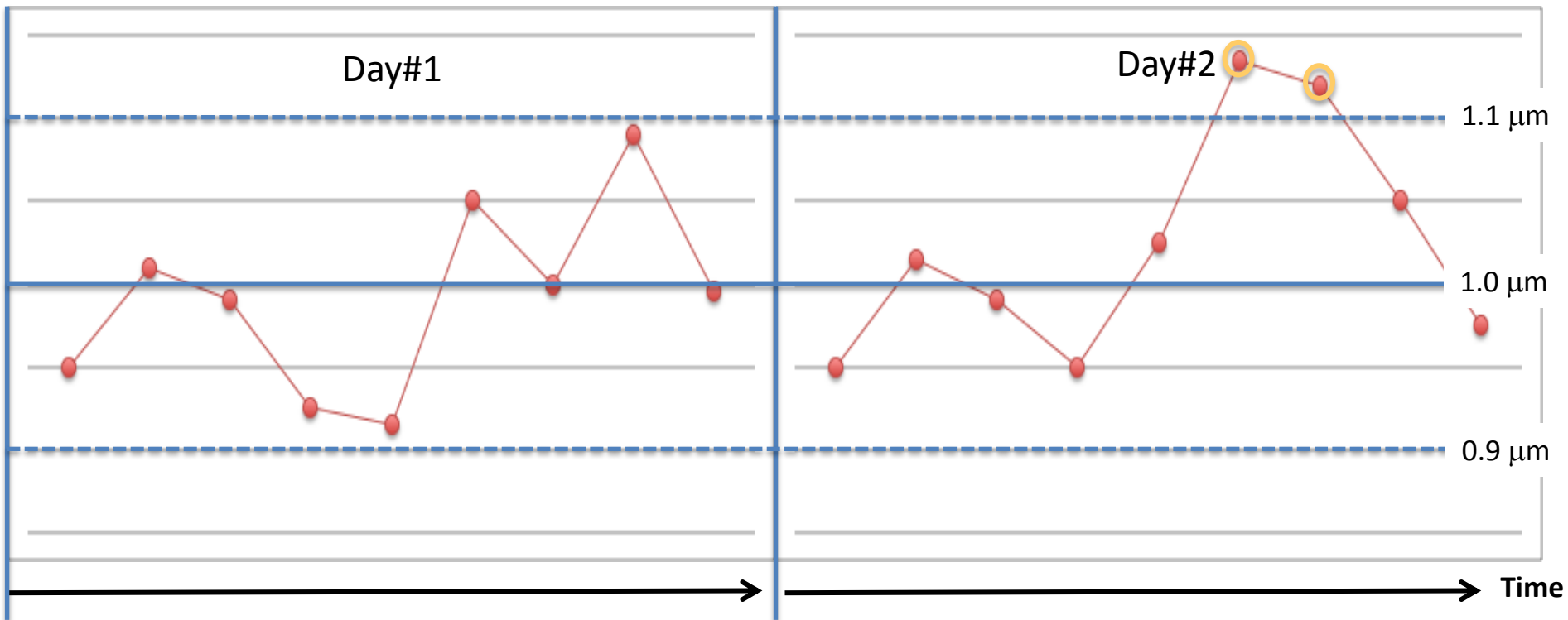
Variability

Photoresist Thickness



Variability

Photoresist Thickness

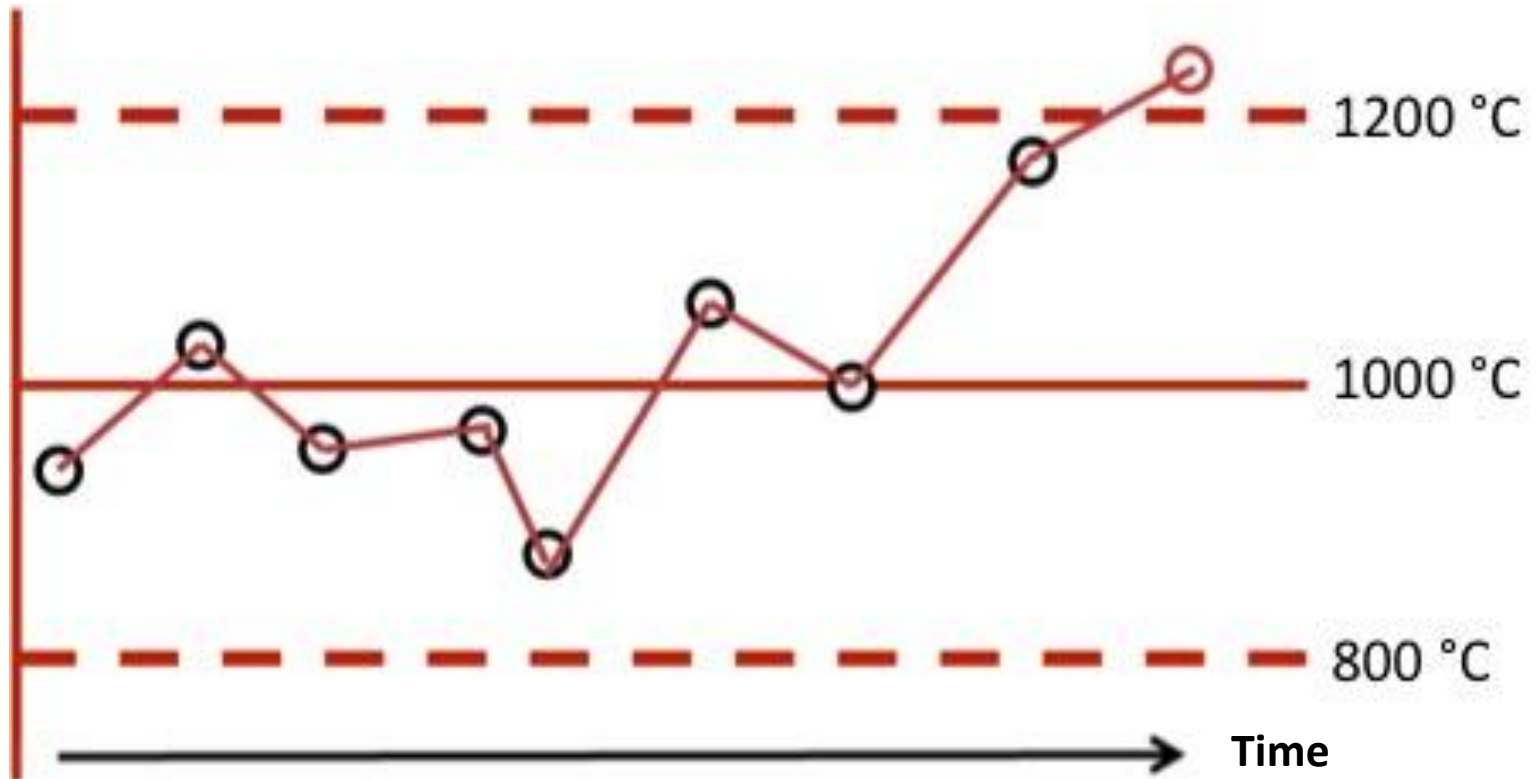


Common Cause Variation
Controlled Variation

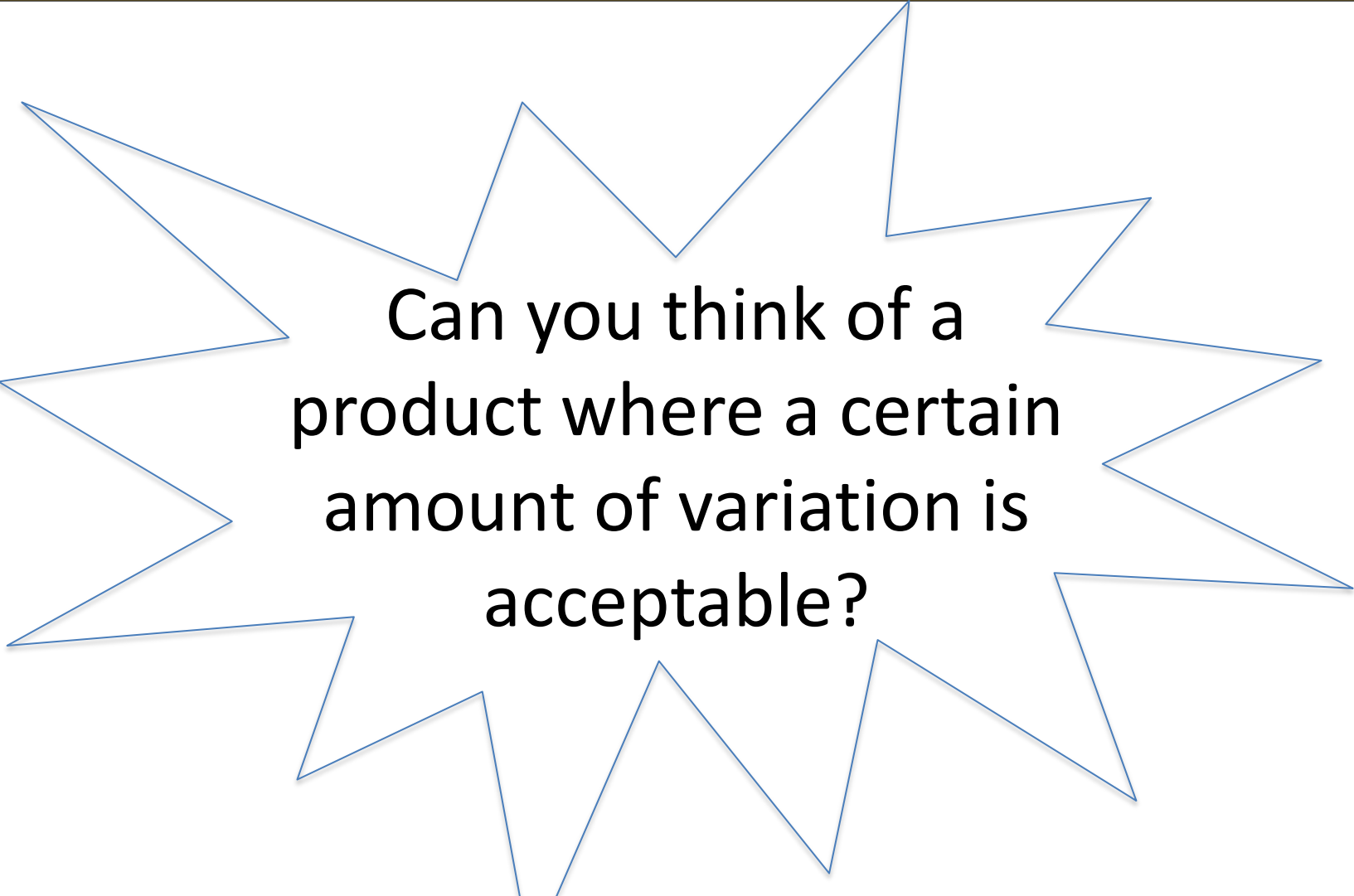
Special Cause Variation
Uncontrolled Variation

Another Example

Process Temperature



Desired Variation



Can you think of a product where a certain amount of variation is acceptable?

Desired Variation

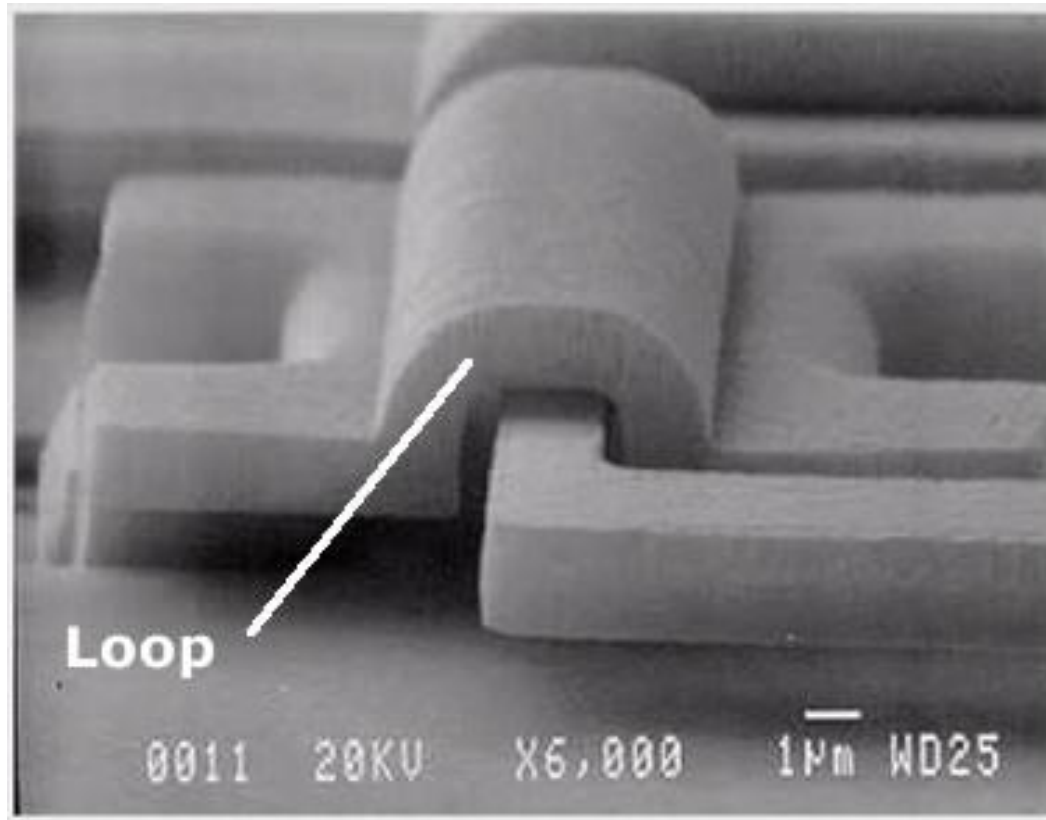


Can you think of a product where a certain amount of variation is acceptable?

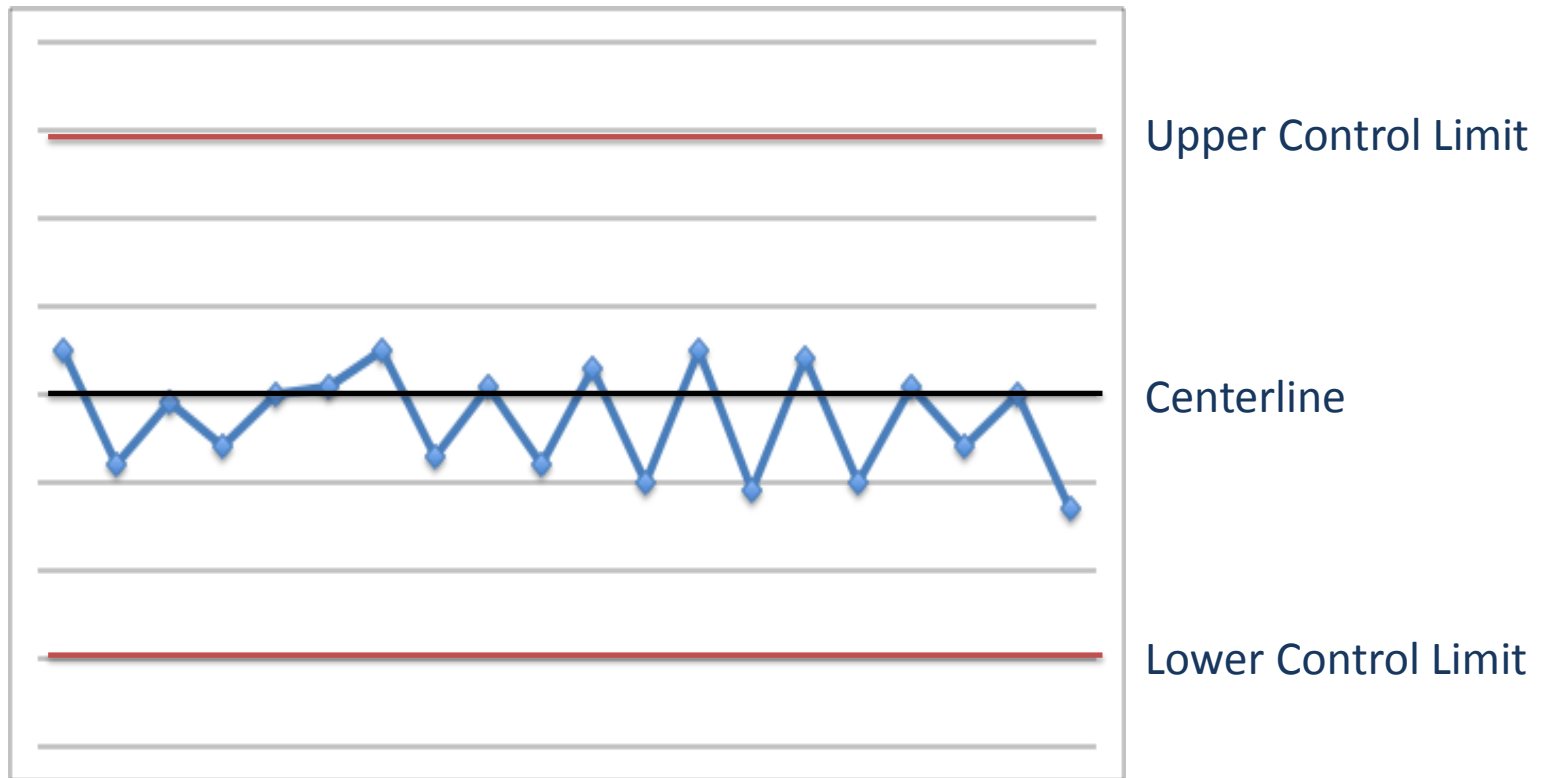


Variation in Microsystems

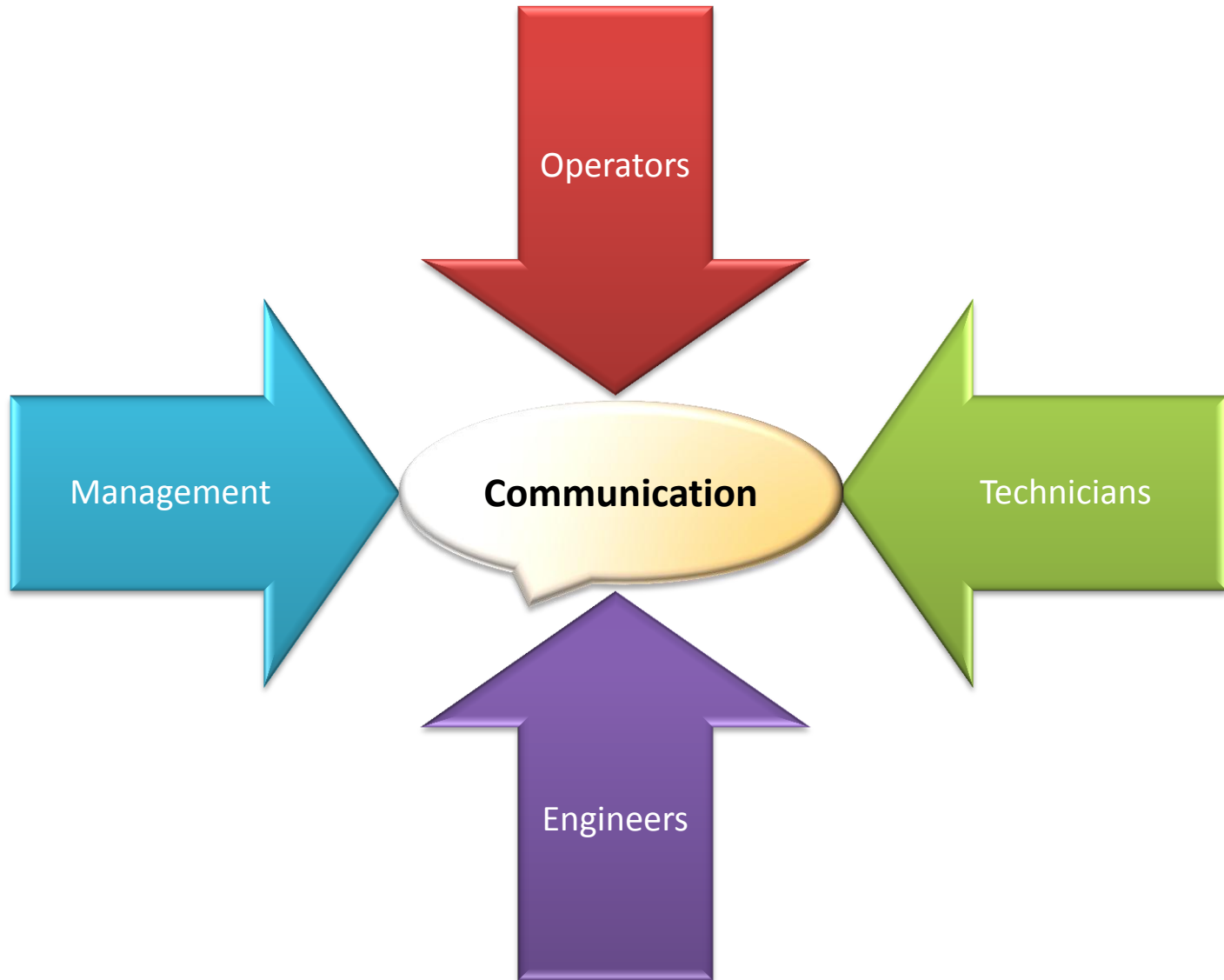
Hinge System



Statistical Process Control and Variation

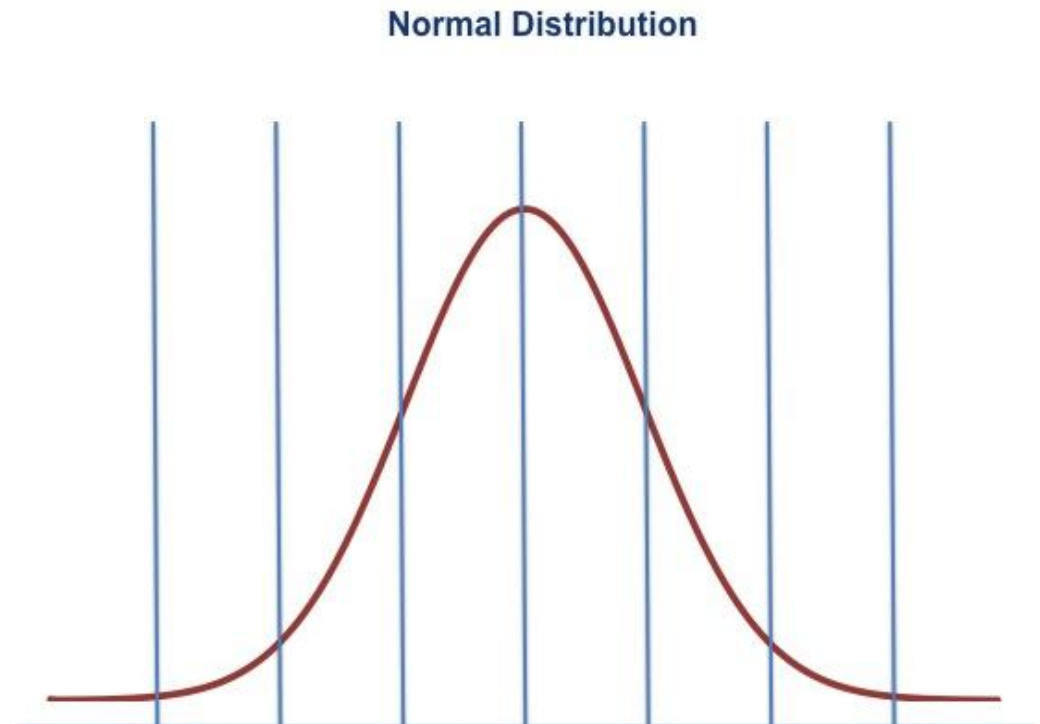


Communication is KEY!



Statistics for Statistical Process Control

- Statistics for Central Tendency
 - Sample Median
 - Sample Mean
- Statistics for Variability
 - Sample Range
 - Sample Variance
 - Sample Standard Deviation



Sample Median – Central Tendency

Sample Median

- Represents the data value that is “physically” in the middle of the sample set when arranged in numerical order.

Example:

- Given the data set: 2,4,1,5,3
- Order the data: 1,2,3,4,5
- **Question: What is the Median?**

Sample Median – Central Tendency

Sample Median

- Represents the data value that is “physically” in the middle of the sample set when arranged in numerical order.

Example:

- Given the data set: 2, 4, 1, 5, 3
- Order the data: 1, 2, **3**, 4, 5

Example:

- Given the data set: 2, 4, 1, 5, 1, 3
- Order the data: 1, 1, 2, 3, 4, 5
- Median is the average of the 2 middle #'s: 2 and 3
- Median = **2.5**

Sample Mean – Central Tendency

Mean

- Universal or Arithmetic Mean = μ
- Sample Mean = \bar{X}
- Mean of a collection of sample Means = $\bar{\bar{X}}$

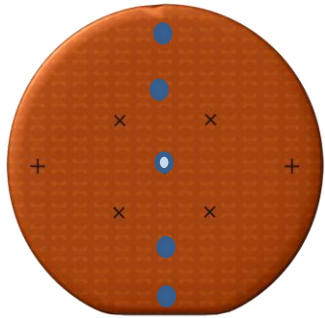
Calculation of Mean

$$\mu = \frac{\sum x_n}{n}$$

5 Resist Thickness Values: 2.87, 2.99, 3.01, 3.15, 2.98 Microns

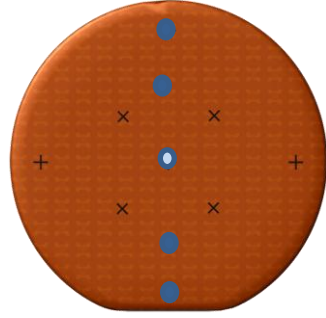
$$\mu = \bar{X} = \frac{2.87 + 2.99 + 3.01 + 3.15 + 2.98}{5} = 3.00 \text{ microns} \quad \text{Sample Mean}$$

What is $\bar{\bar{X}}$?



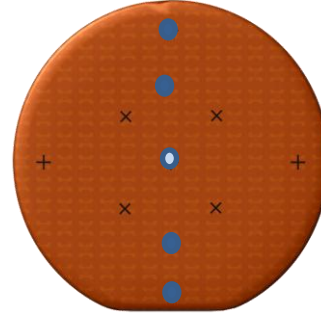
Wafer #1

3.23
3.09
4.82
4.16
2.11



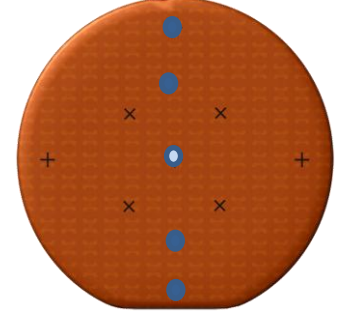
Wafer #2

3.43
4.29
1.95
4.55
2.37



Wafer #3

3.74
2.01
1.58
4.89
1.38



Wafer #4

2.52
2.49
1.68
4.18
1.61

Wafer #1 Sample Mean

$\bar{X} = 3.48$
microns

Wafer #2 Sample Mean

$\bar{X} = 3.32$
microns

Wafer #3 Sample Mean

$\bar{X} = 2.72$
microns

Wafer #4 Sample Mean

$\bar{X} = 2.49$
microns

$$\bar{\bar{X}} = \frac{3.48 + 3.32 + 2.72 + 2.49}{4} = 3.00 \text{ microns}$$

Sample Range

Statistics for Variability

Statistics for Variability

- Sample Range
- Sample Variance
- Sample Standard Deviation

- *Sample Range*

- The difference between the maximum value minus the minimum value.

2.87, 2.99, 3.01, 3.15, 2.98

Question – What is the Sample Range?

Sample Range

Statistics for Variability

Statistics for Variability

- Sample Range
- Sample Variance
- Sample Standard Deviation

- *Sample Range*

- The difference between the maximum value minus the minimum value.

2.87, 2.99, 3.01, 3.15, 2.98

$$3.15 - 2.87 = 0.28 \text{ Sample Range}$$

Sample Variance

Statistics for Variability

- *Sample Variance*
 - How far a set of numbers are spread out.

$$\sigma^2 = \frac{\sum_{i=1}^n (x_i - \mu)^2}{n - 1}$$

- 5 Resist Thickness Values: 2.87, 2.99, 3.01, 3.15, 2.98 microns
- Mean = 3.00 micros
- $\sigma^2 = 0.01$ Square Microns

Sample Standard Deviation

Statistics for Variability

- *Sample Standard Deviation*

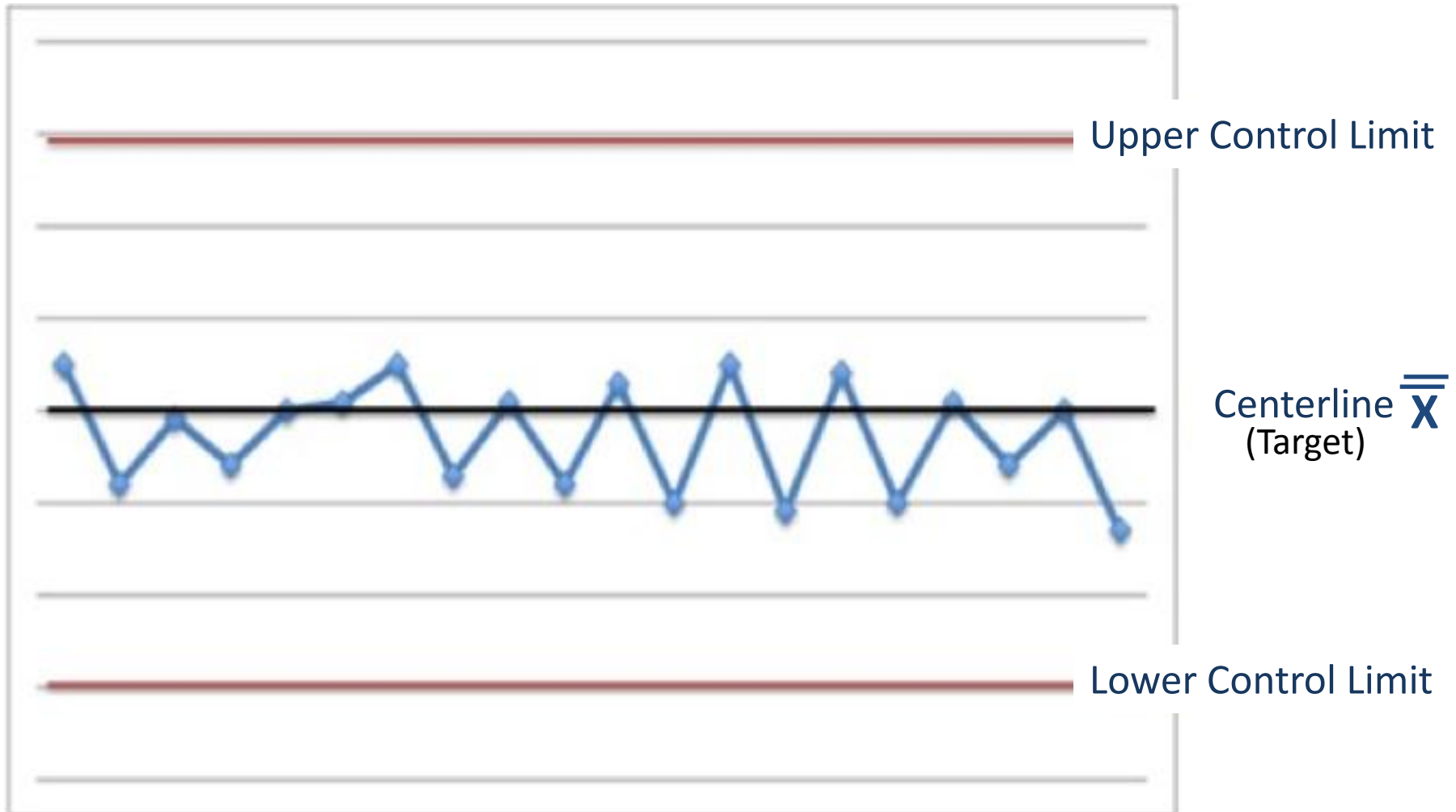
- Measurement of how the data are distributed around the sample mean and within a range of values.

$$\sigma = \sqrt{\sigma^2} = \sqrt{\frac{\sum_{i=1}^n (x_i - \mu)^2}{n - 1}}$$

- $\sigma^2 = 0.01 \text{ micron}^2$
- $\sigma = 0.1 \text{ micron}$

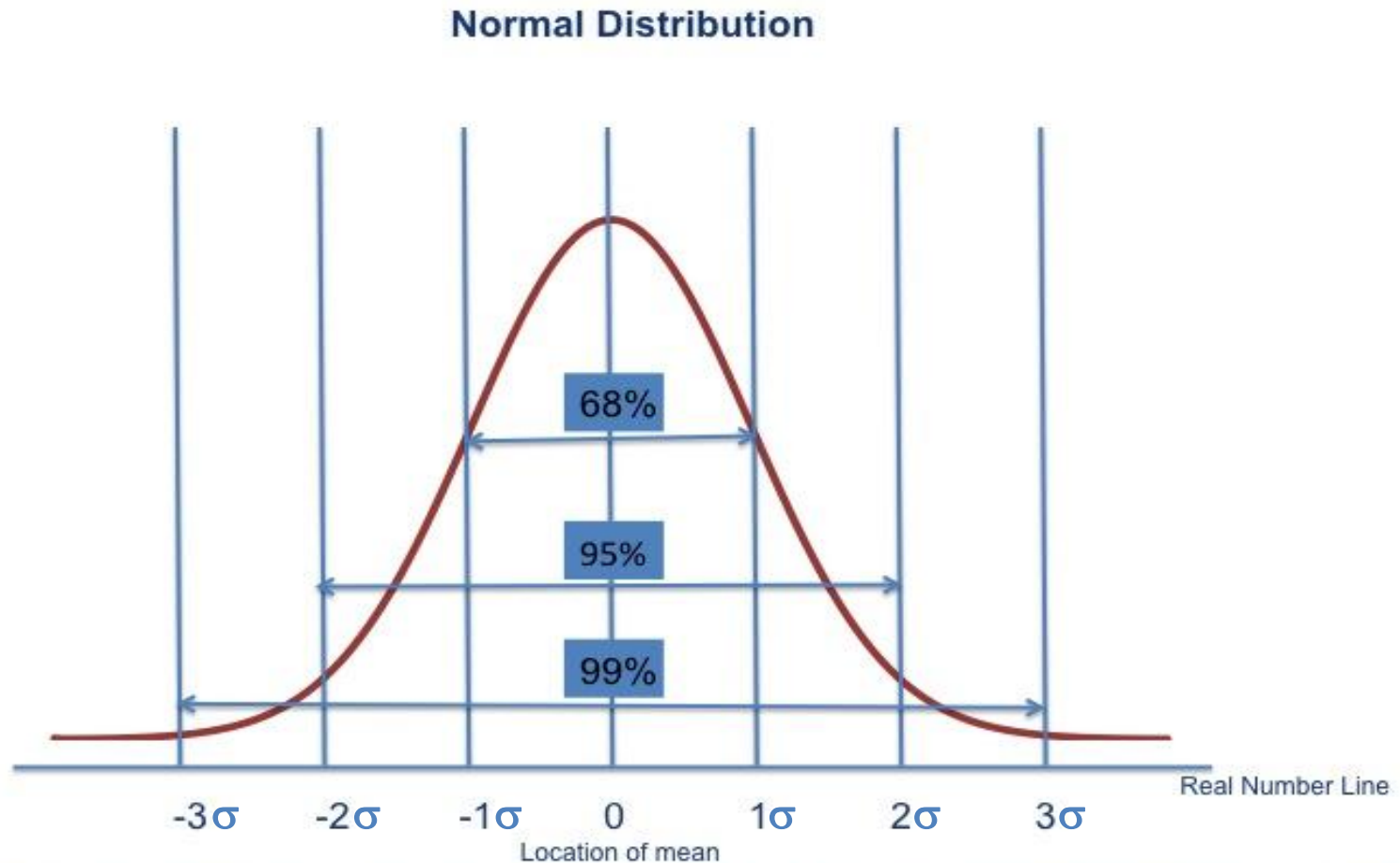
Let's Have Fun with Control Charts!

\bar{X} -Chart



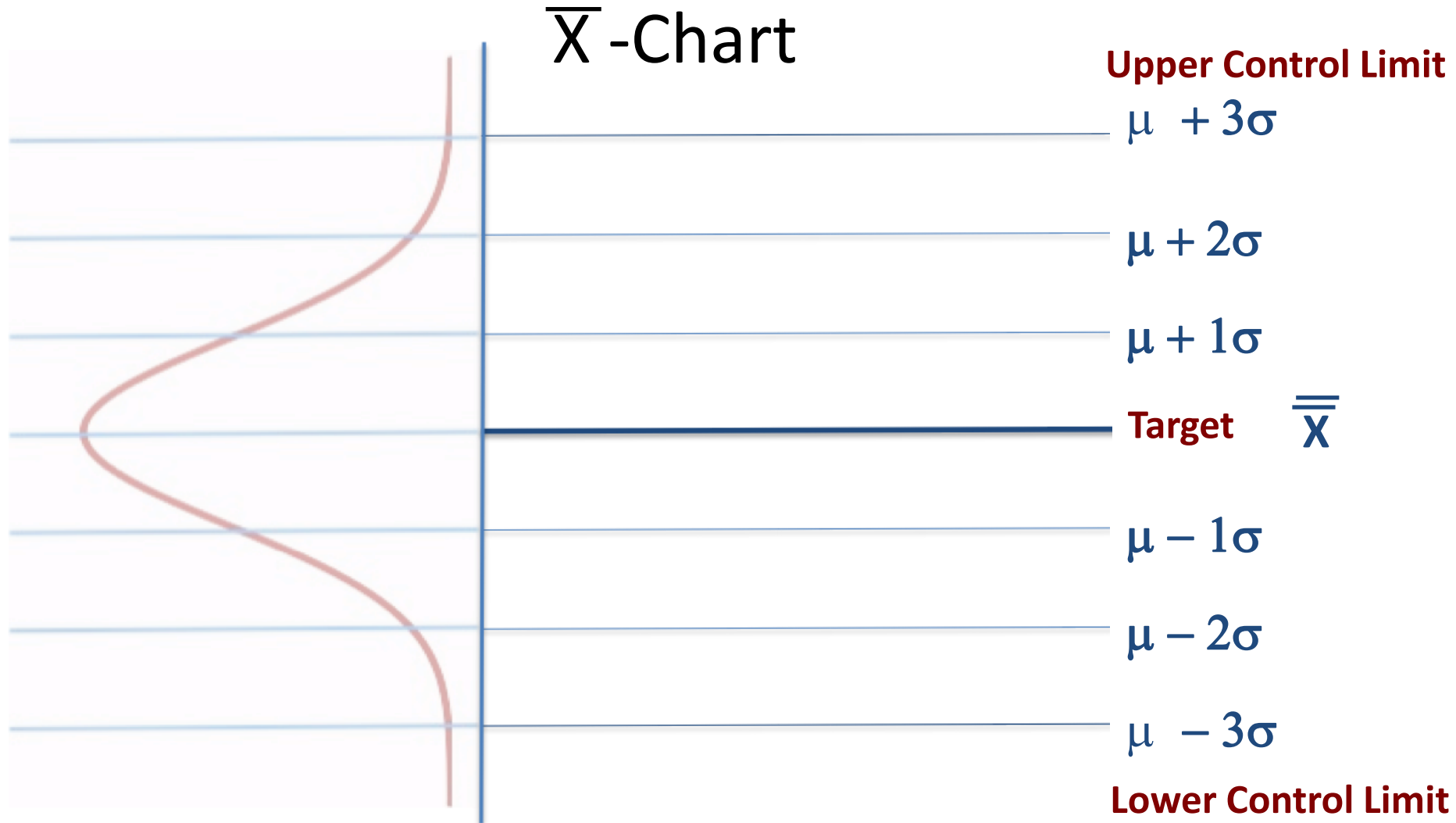
Normal Distribution

Yes, it does matter



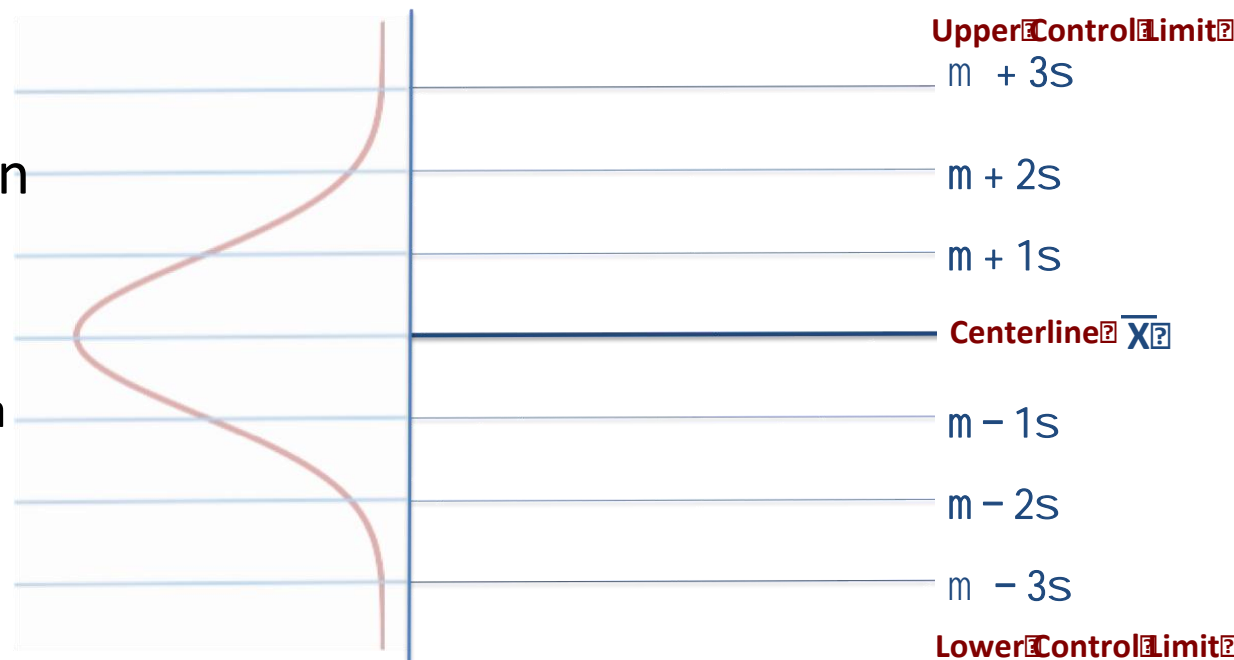
Axis scale gives number of standard deviations away from the mean (negative implies "below the mean")

Control Chart Basics



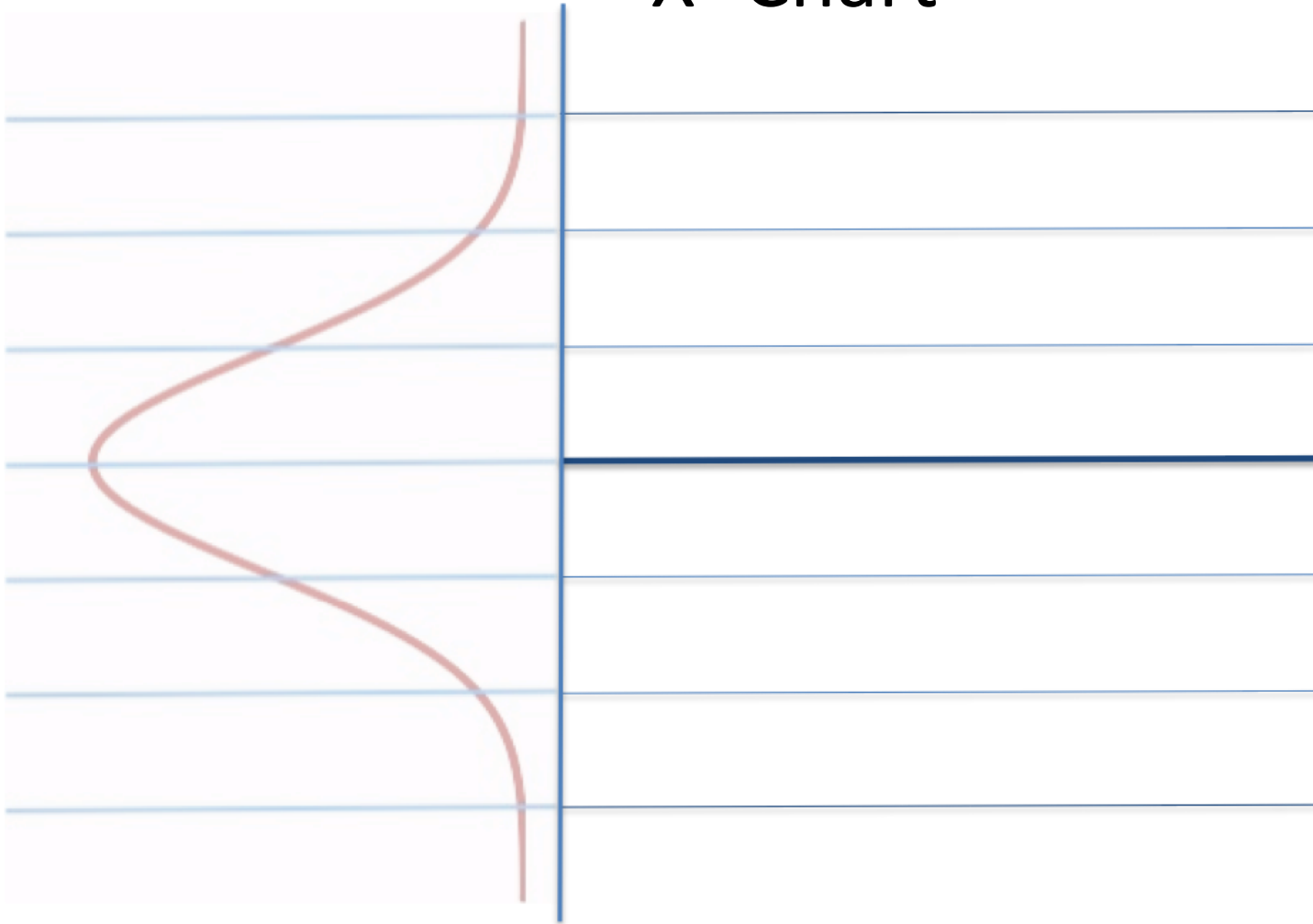
Control Chart Basics

- X axis is time based
- Monitors process to detect special cause variation and manage common cause variation
- Common Cause Variation
 - Due to room temperature change
 - Line personnel
- Special Cause Variation
 - Changes in process
 - Unexpected events
 - Change in vendors of a product ingredient
 - Leaks in a vacuum line



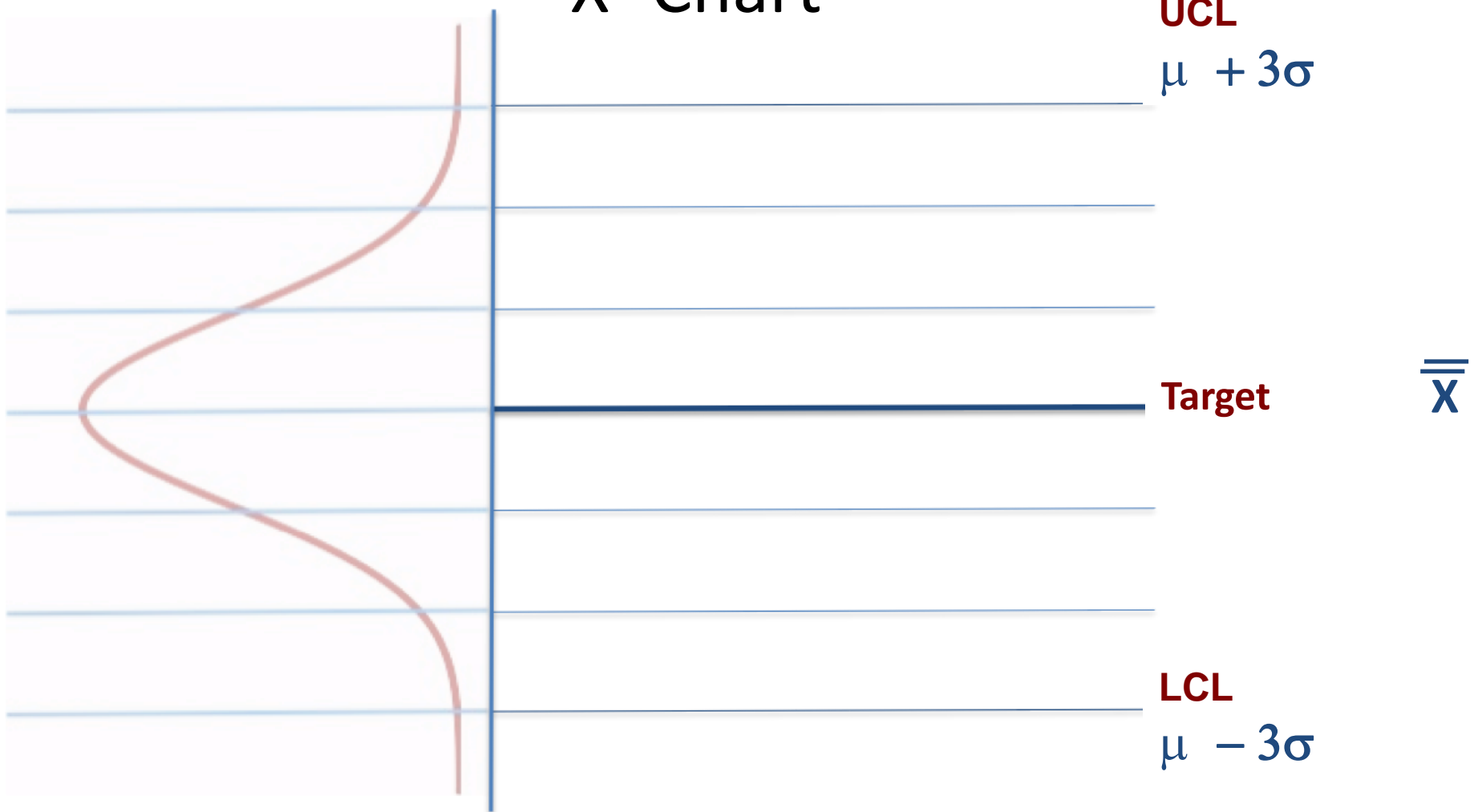
Control Chart Basics

\bar{X} -Chart



Control Chart Basics

\bar{X} -Chart



Control Chart Basics

\bar{X} or $\mu = 3.00$ microns
 $\sigma = 0.1$ microns

\bar{X} -Chart

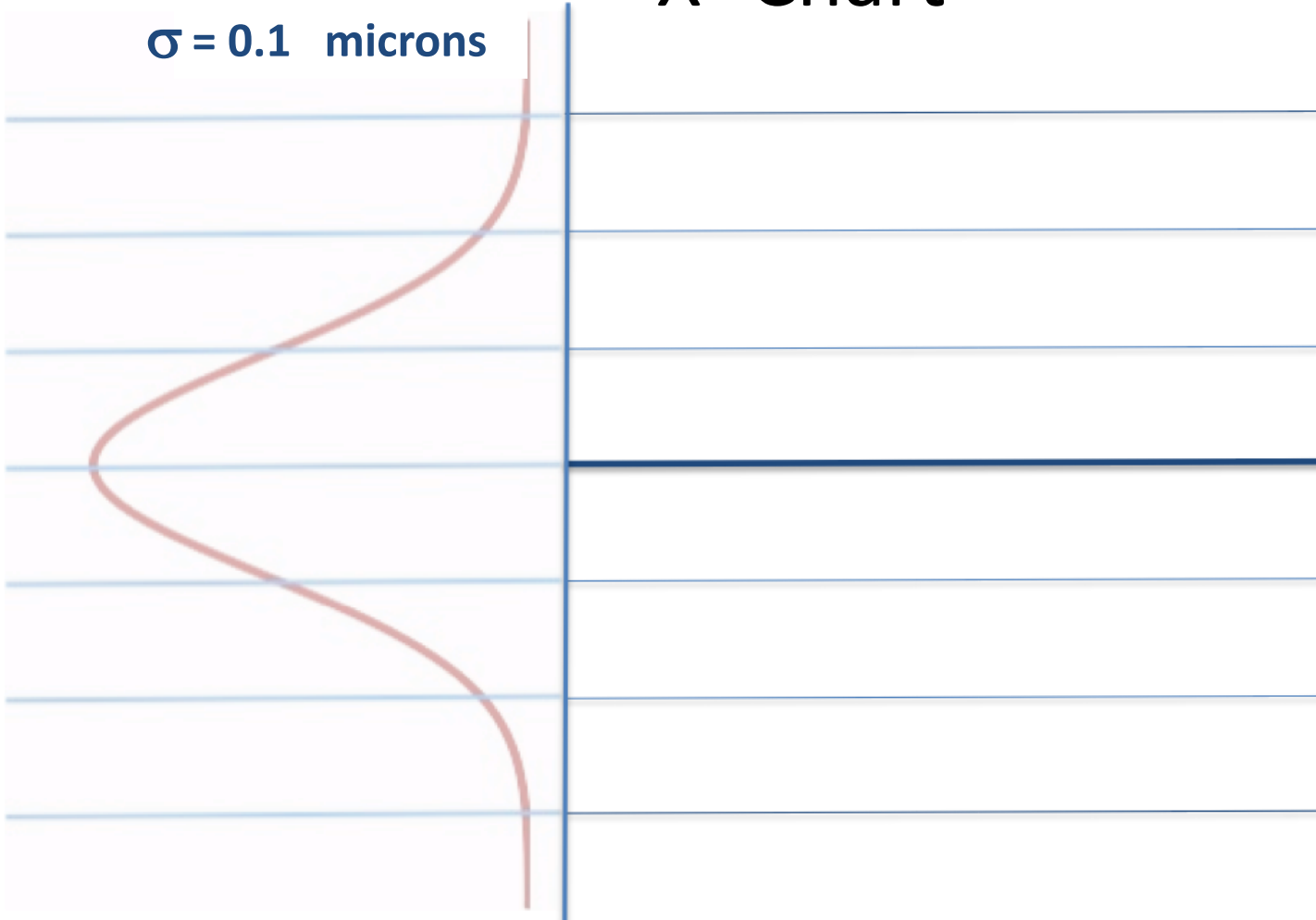
UCL

$$\mu + 3\sigma$$
$$3 + (3 \cdot 0.1) = 3.03$$

Target = 3.00 $\bar{\bar{X}}$

LCL

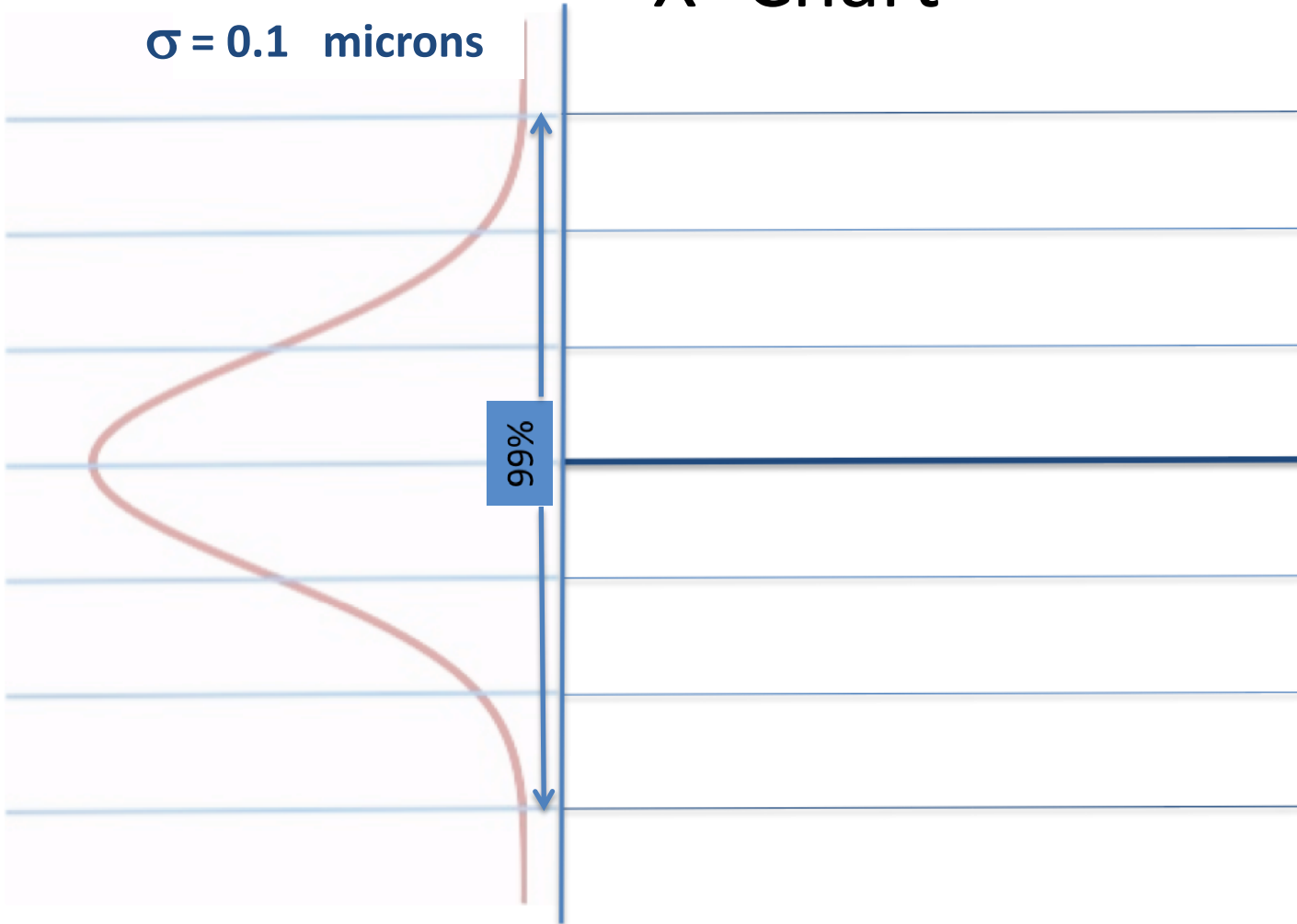
$$\mu - 3\sigma$$
$$3 - (3 \cdot 0.1) = 2.97$$



Control Chart Basics

\bar{X} or $\mu = 3.00$ microns
 $\sigma = 0.1$ microns

\bar{X} -Chart



UCL

$$\mu + 3\sigma$$

$$3 + (3 \times 0.1) = 3.03$$

$$\mu + 2\sigma$$

$$\mu + 1\sigma$$

Target = 3.00 $\bar{\bar{X}}$

$$\mu - 1\sigma$$

$$\mu - 2\sigma$$

LCL

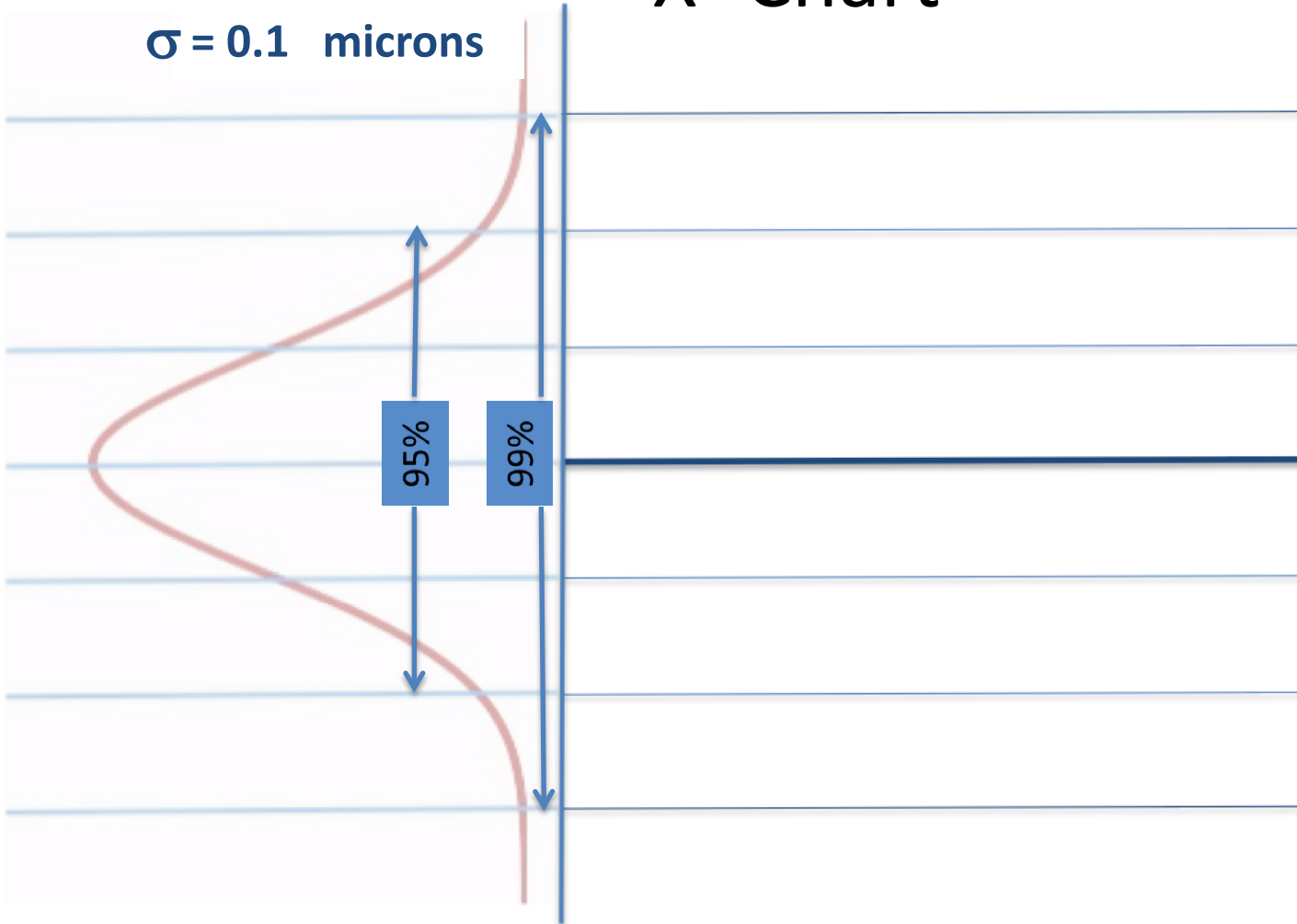
$$\mu - 3\sigma$$

$$3 - (3 \times 0.1) = 2.97$$

Control Chart Basics

\bar{X} or $\mu = 3.00$ microns
 $\sigma = 0.1$ microns

\bar{X} -Chart



UCL

$$\mu + 3\sigma$$

$$3 + (3 \times 0.1) = 3.03$$

$$\mu + 2\sigma$$

$$\mu + 1\sigma$$

Target = 3.00 $\bar{\bar{X}}$

$$\mu - 1\sigma$$

$$\mu - 2\sigma$$

LCL

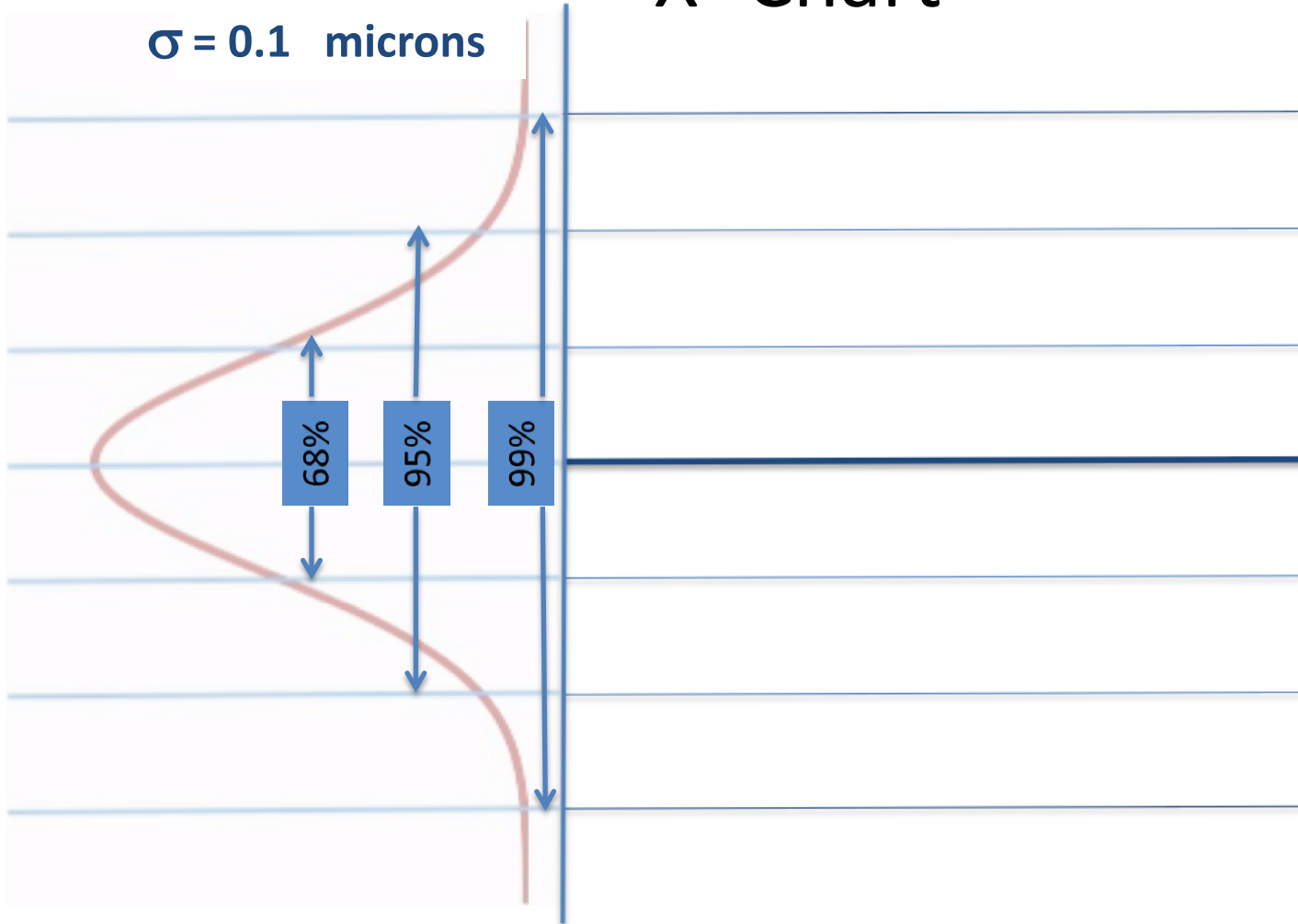
$$\mu - 3\sigma$$

$$3 - (3 \times 0.1) = 2.97$$

Control Chart Basics

\bar{X} or $\mu = 3.00$ microns
 $\sigma = 0.1$ microns

\bar{X} -Chart



UCL

$$\mu + 3\sigma$$

$$3 + (3 \cdot 0.1) = 3.03$$

$$\mu + 2\sigma$$

$$\mu + 1\sigma$$

Target = 3.00 $\bar{\bar{X}}$

$$\mu - 1\sigma$$

$$\mu - 2\sigma$$

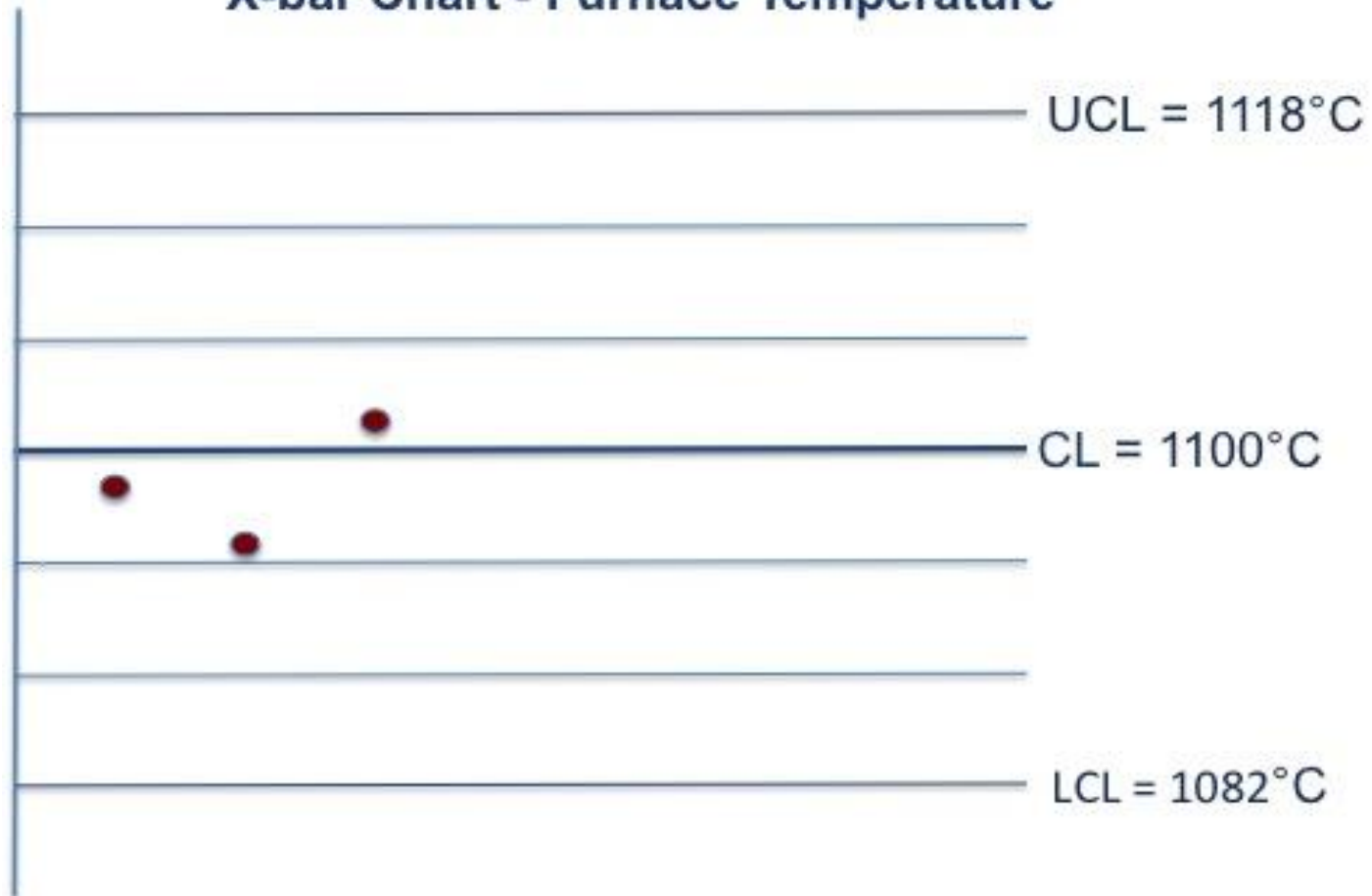
LCL

$$\mu - 3\sigma$$

$$3 - (3 \cdot 0.1) = 2.97$$

Control Chart Basics

Average
X-bar Chart - Furnace Temperature



Shewhart Rules

aka Western Electric Rules (WECO)

8 Rules to Signal an Out of Control Process

– Developed by a Western Electric Engineer – Walter Shewhart

Rule 1: A single point outside the $\mu \pm 3\sigma$ zone.

Rule 2: Two out of three successive points outside $\mu \pm 2\sigma$ zone.

Rule 3: Four out of five successive points outside $\mu \pm 1\sigma$ zone.

Rule 4: Eight or more successive numbers either strictly above or strictly below the mean (the center).

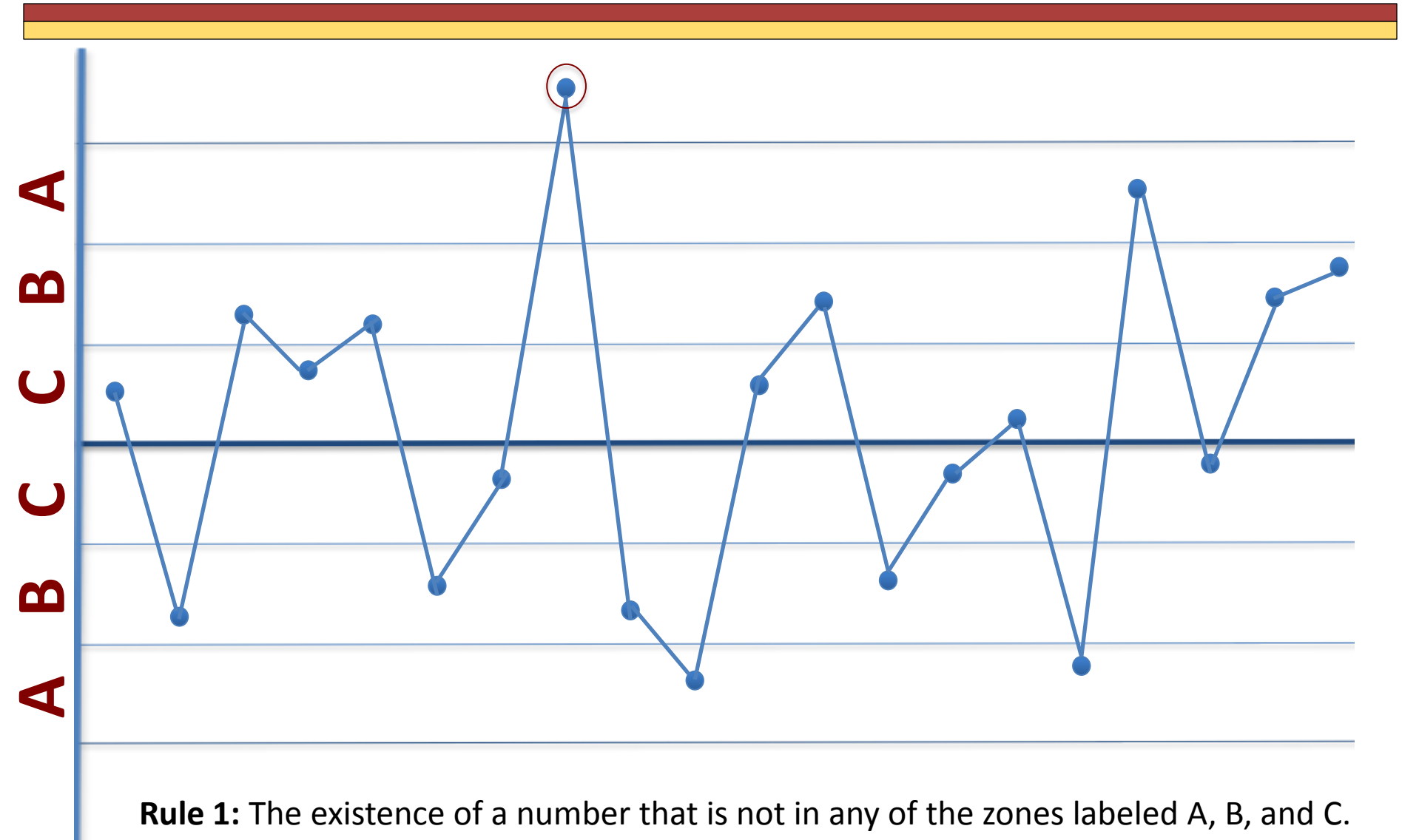
Rule 5: Six or more successive numbers showing a continuous increase or continuous decrease.

Rule 6: Fourteen or more successive numbers that oscillate in size (i.e. smaller, larger, smaller, larger)

Rule 7: Eight or more successive numbers that avoid $\mu \pm 1\sigma$ zone.

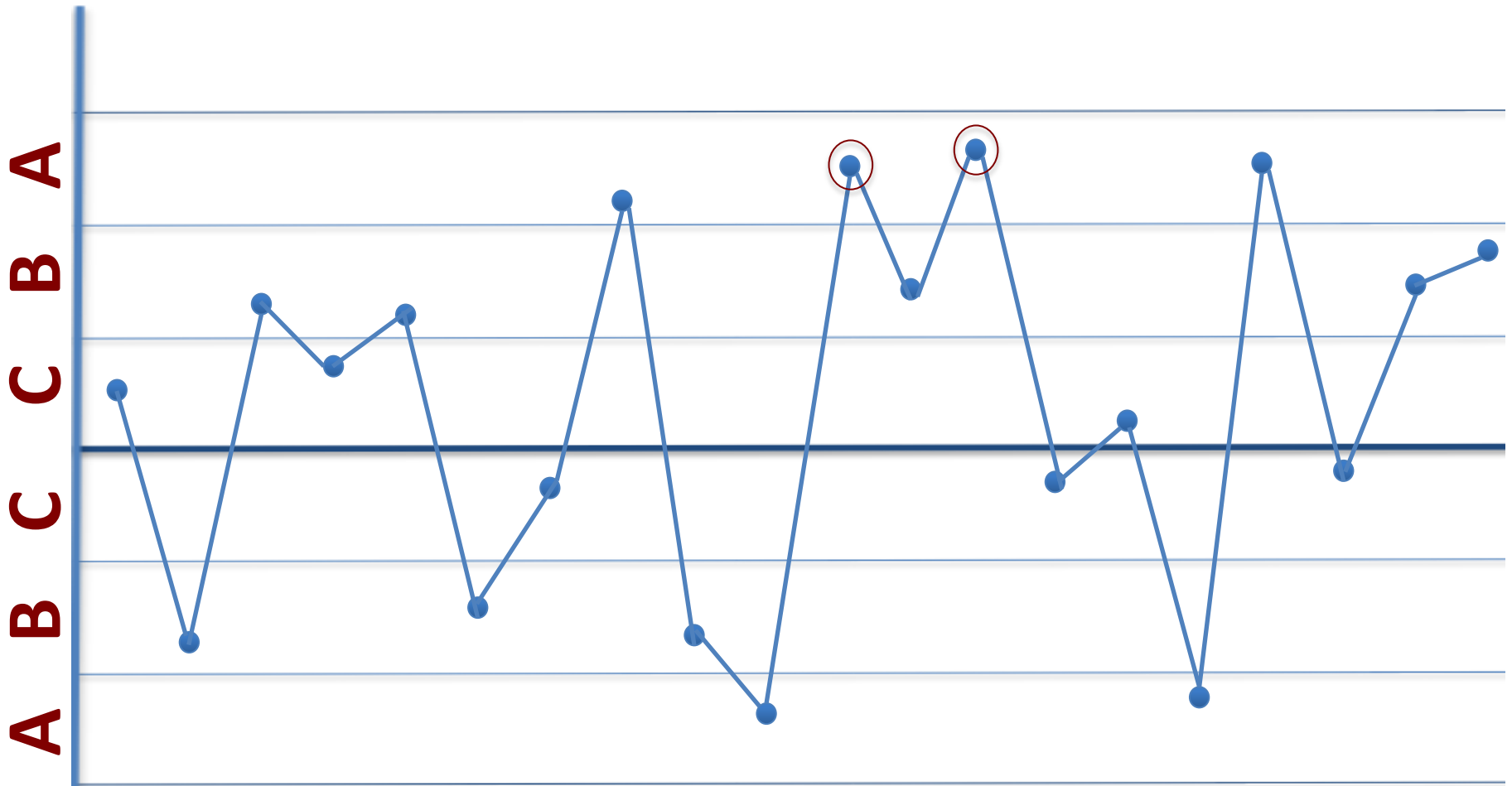
Rule 8: Fifteen successive points fall into $\mu \pm 1\sigma$ zone only, to either side of the centerline.

Shewhart Rules – Rule #1



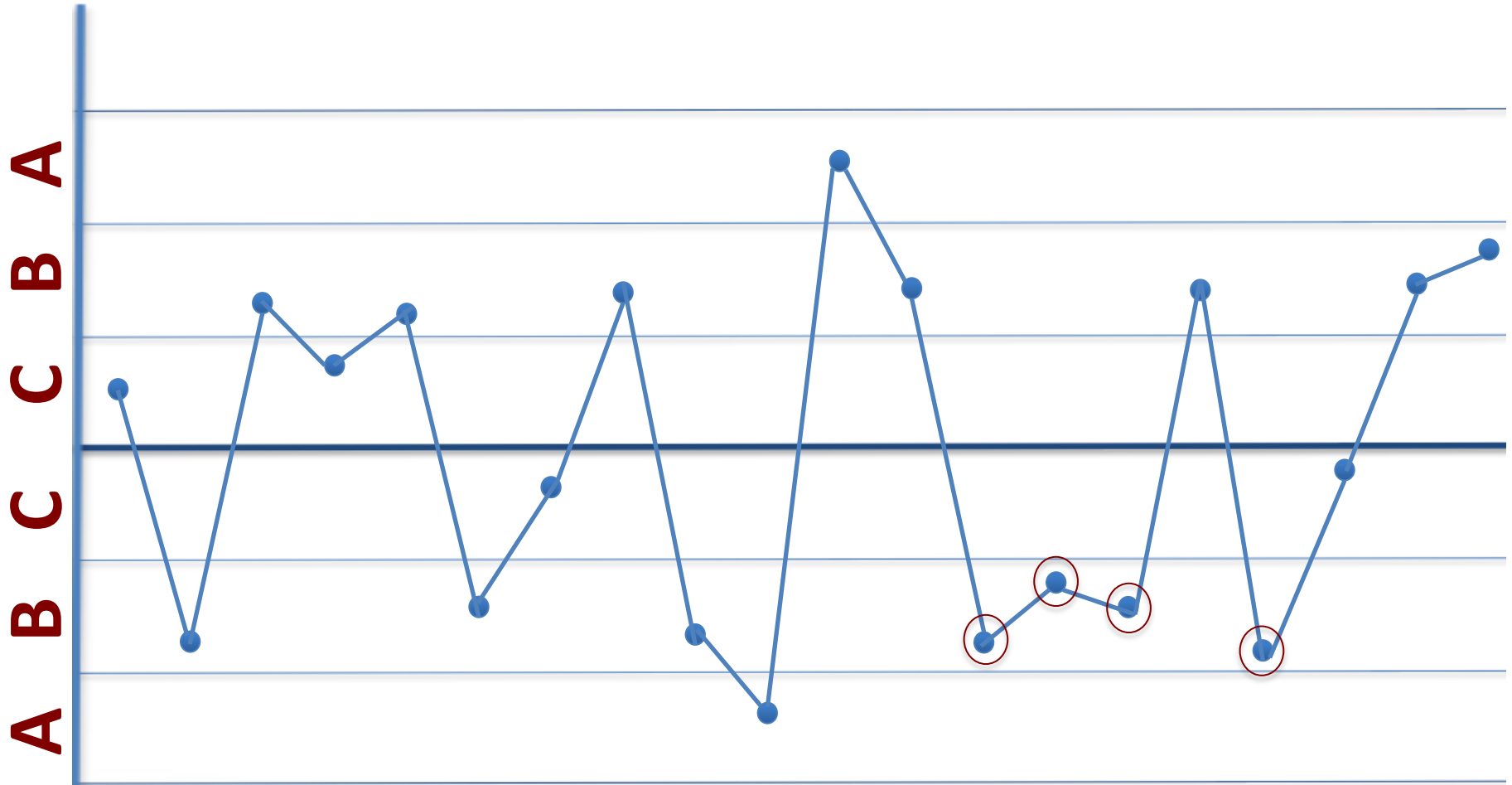
Rule 1: The existence of a number that is not in any of the zones labeled A, B, and C. (See special, encircled point above.) This would be a single point outside the $\mu \pm 3\sigma$ zone.

Shewhart Rules – Rule #2



Rule 2: Two out of three successive numbers in a zone A or beyond (by beyond we mean away from the mean). This would be two out of three successive points outside $\mu \pm 2\sigma$ zone.

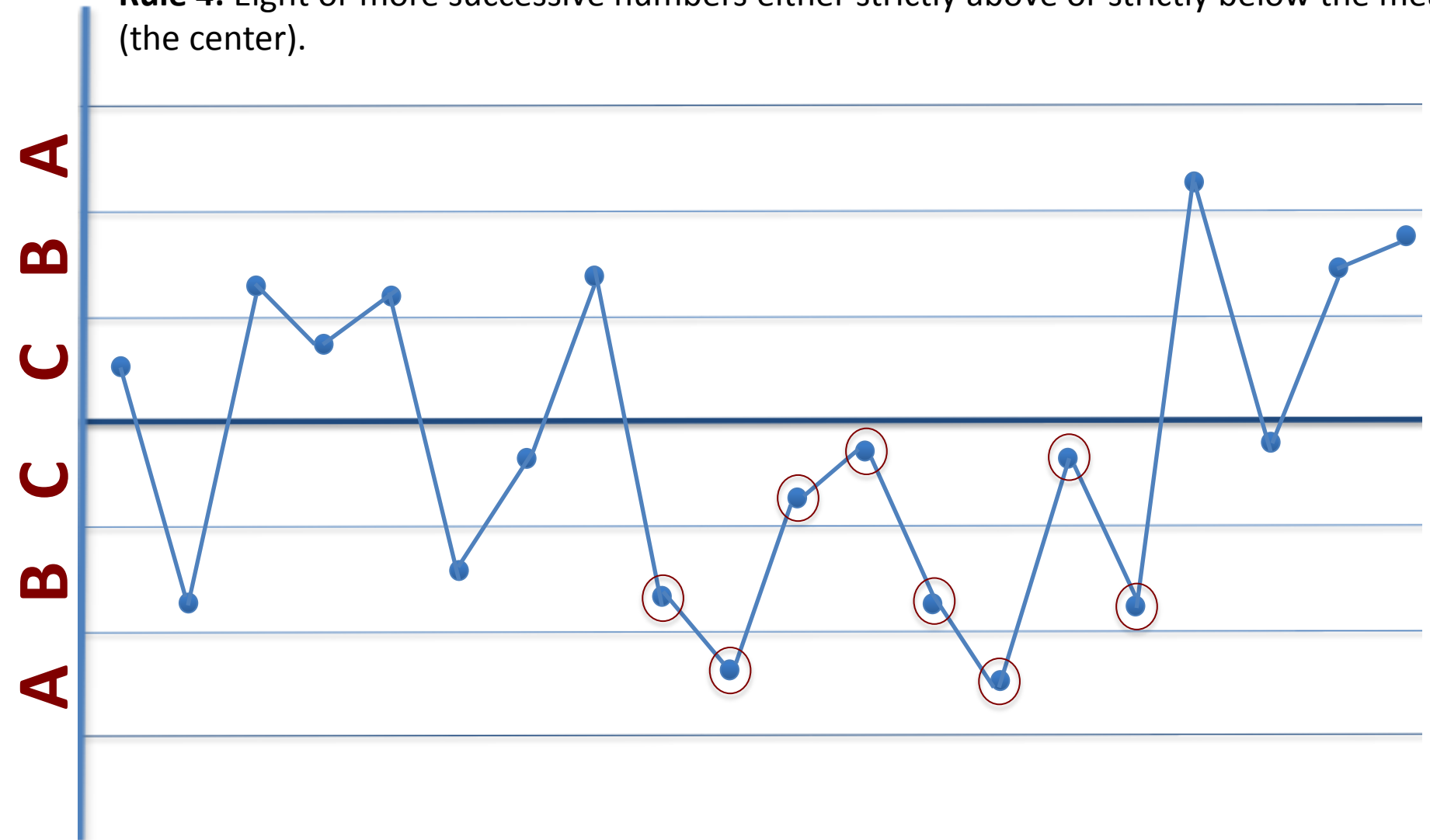
Shewhart Rules – Rule #3



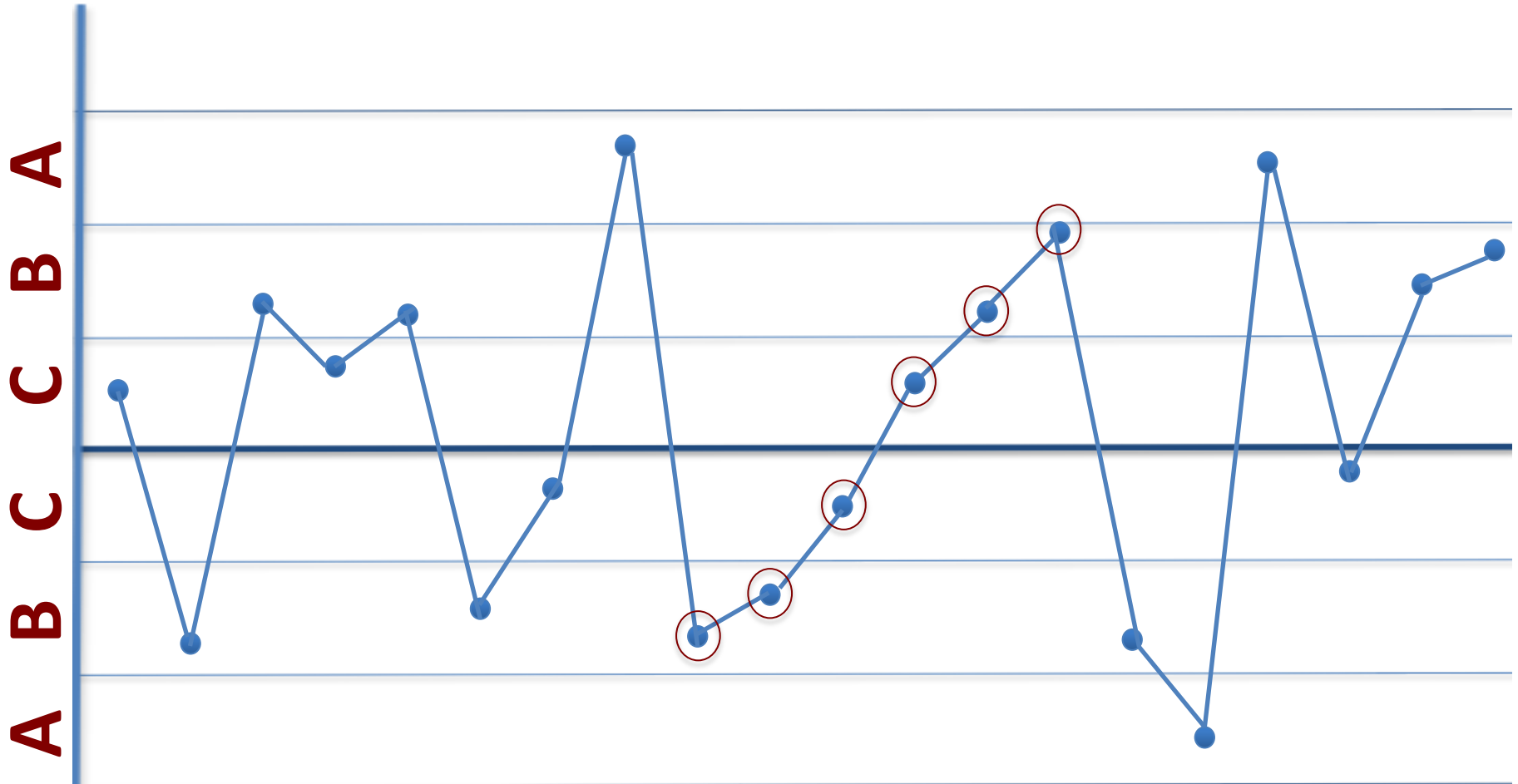
Rule 3: Four out of five successive numbers in a zone B or beyond. This would be four out of five successive points outside $\mu \pm 1\sigma$ zone.

Shewhart Rules – Rule #4

Rule 4: Eight or more successive numbers either strictly above or strictly below the mean (the center).



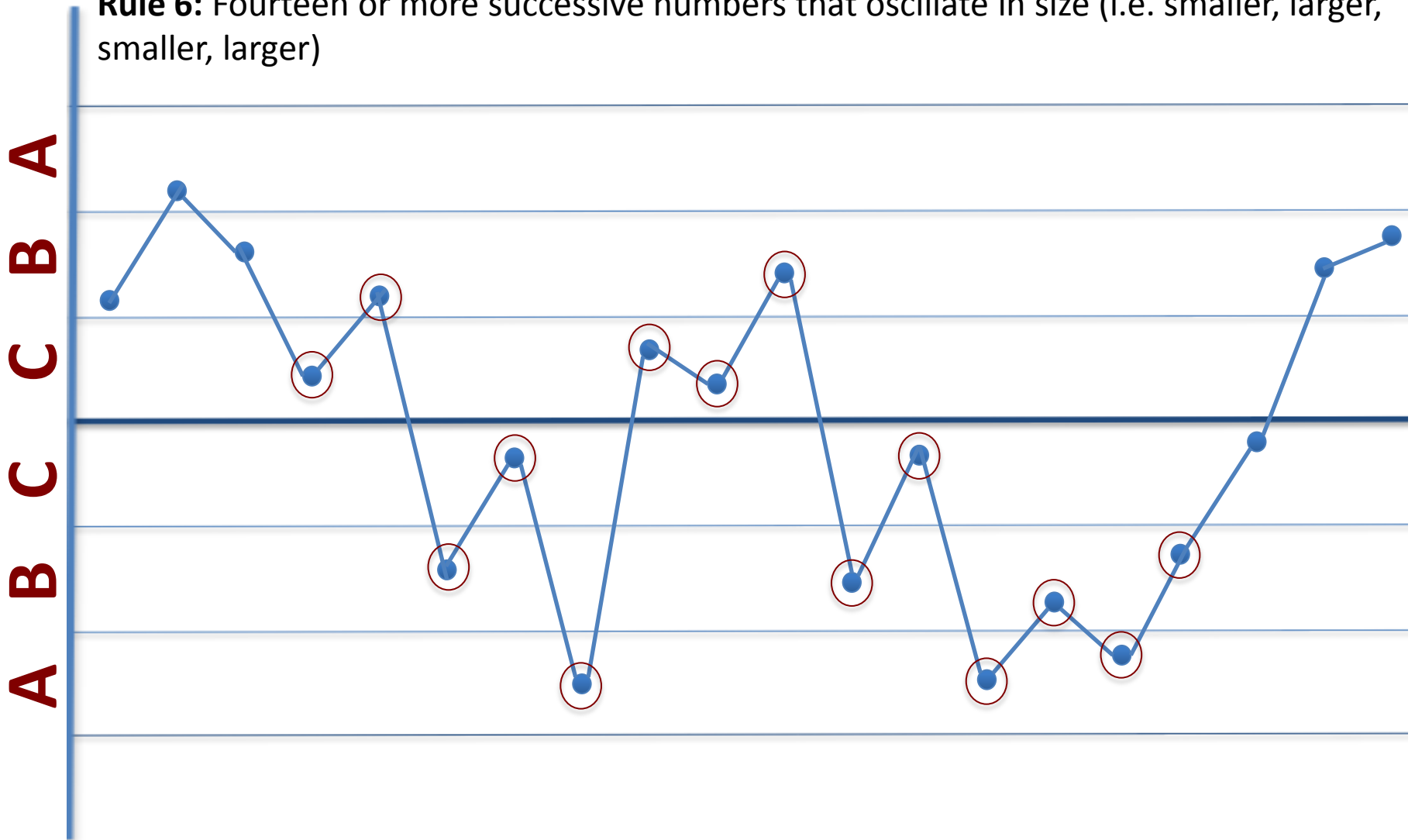
Shewhart Rules – Rule #5



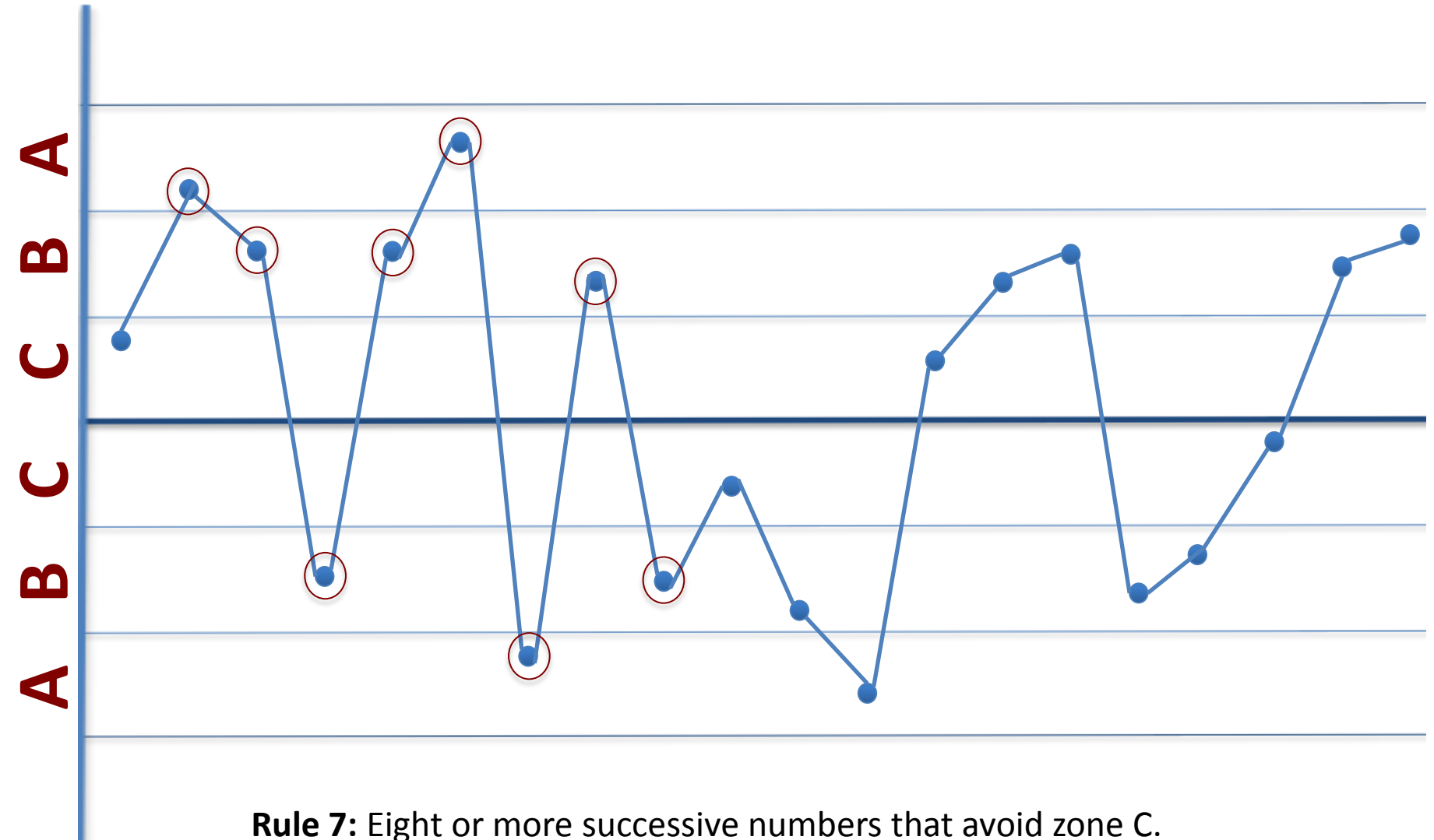
Rule 5: Six or more successive numbers showing a continuous increase or continuous decrease.

Shewhart Rules – Rule #6

Rule 6: Fourteen or more successive numbers that oscillate in size (i.e. smaller, larger, smaller, larger)

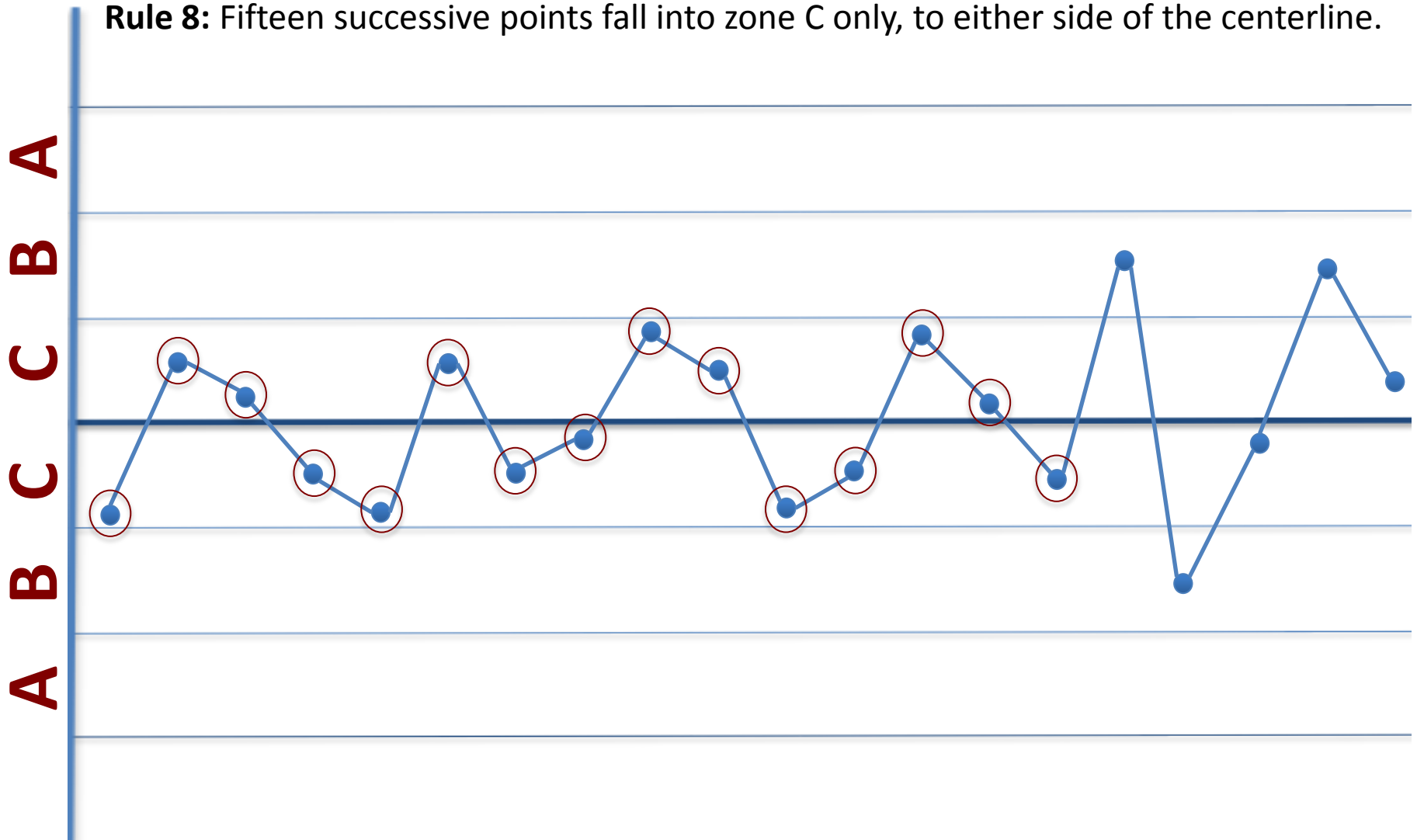


Shewhart Rules – Rule #7



Shewhart Rules – Rule #8

Rule 8: Fifteen successive points fall into zone C only, to either side of the centerline.



Type I and Type II Errors

- 2 Types of Errors: Type I and Type II
- Type I – False Alarm
 - Decision rules lead you to decide that special cause variation is present when in fact it is *not* present.
- Type II – Miss
 - Decision rules lead you *not* to decide that special cause variation is present when in fact it is present.

Question: Let's test the rules

Rule 1: A single point outside the $\mu \pm 3\sigma$ zone.

Rule 2: Two out of three successive points outside $\mu \pm 2\sigma$ zone.

Rule 3: Four out of five successive points outside $\mu \pm 1\sigma$ zone.

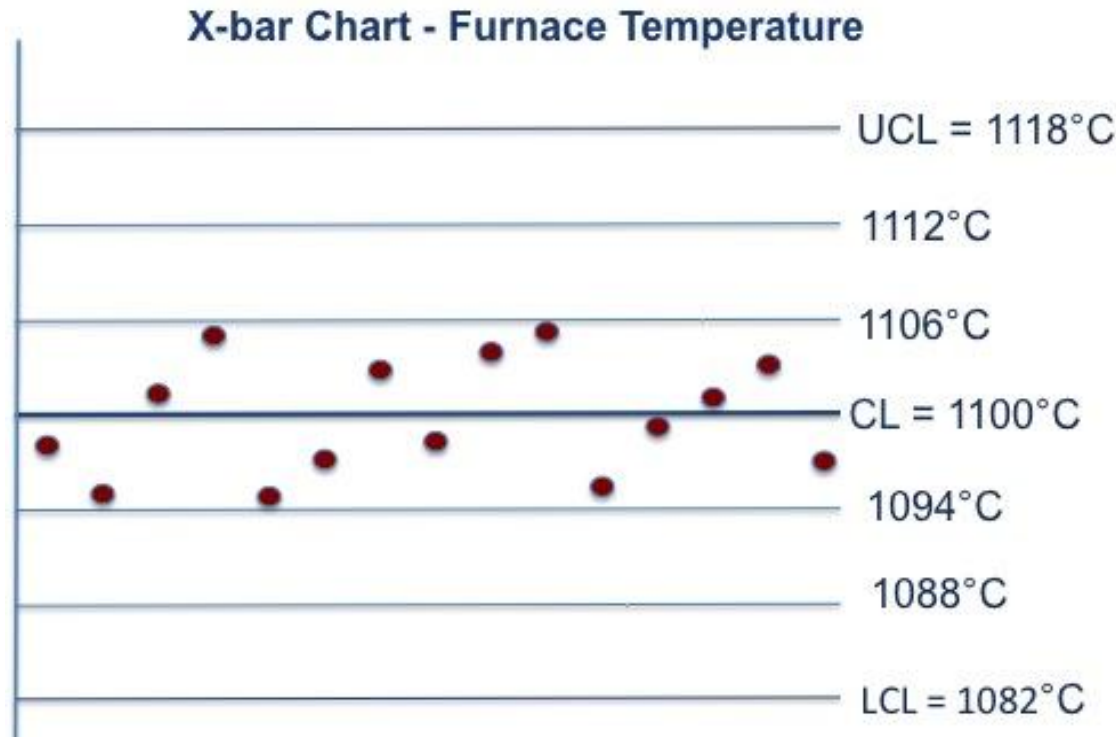
Rule 4: 8 or more successive numbers either strictly above or strictly below the mean.

Rule 5: 6 or more successive numbers showing a continuous increase or continuous decrease.

Rule 6: 14 or more successive numbers that oscillate in size (i.e. smaller, larger, smaller, larger)

Rule 7: 8 or more successive numbers that avoid $\mu \pm 1\sigma$ zone.

Rule 8: 15 successive points fall into $\mu \pm 1\sigma$ zone only, to either side of the centerline or target.



Question: Let's test the rules

Rule 1: A single point outside the $\mu \pm 3\sigma$ zone.

Rule 2: Two out of three successive points outside $\mu \pm 2\sigma$ zone.

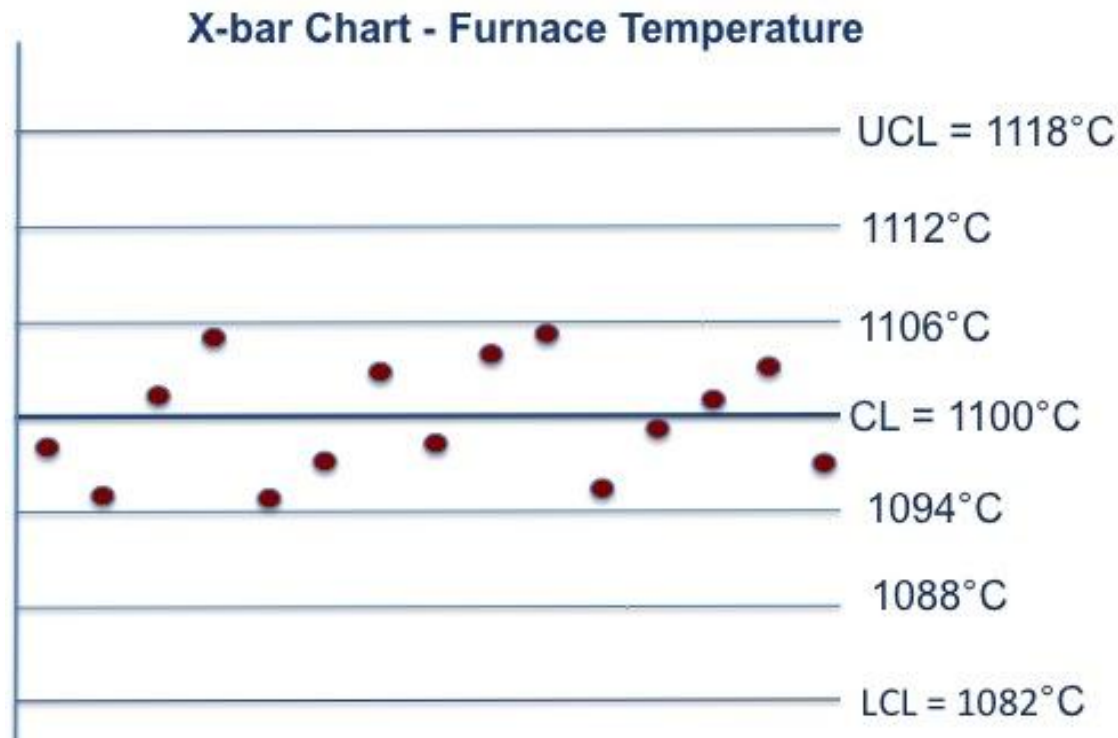
Rule 3: Four out of five successive points outside $\mu \pm 1\sigma$ zone.

Rule 4: 8 or more successive numbers either strictly above or strictly below the mean.

Rule 6: 14 or more successive numbers that oscillate in size (i.e. smaller, larger, smaller, larger)

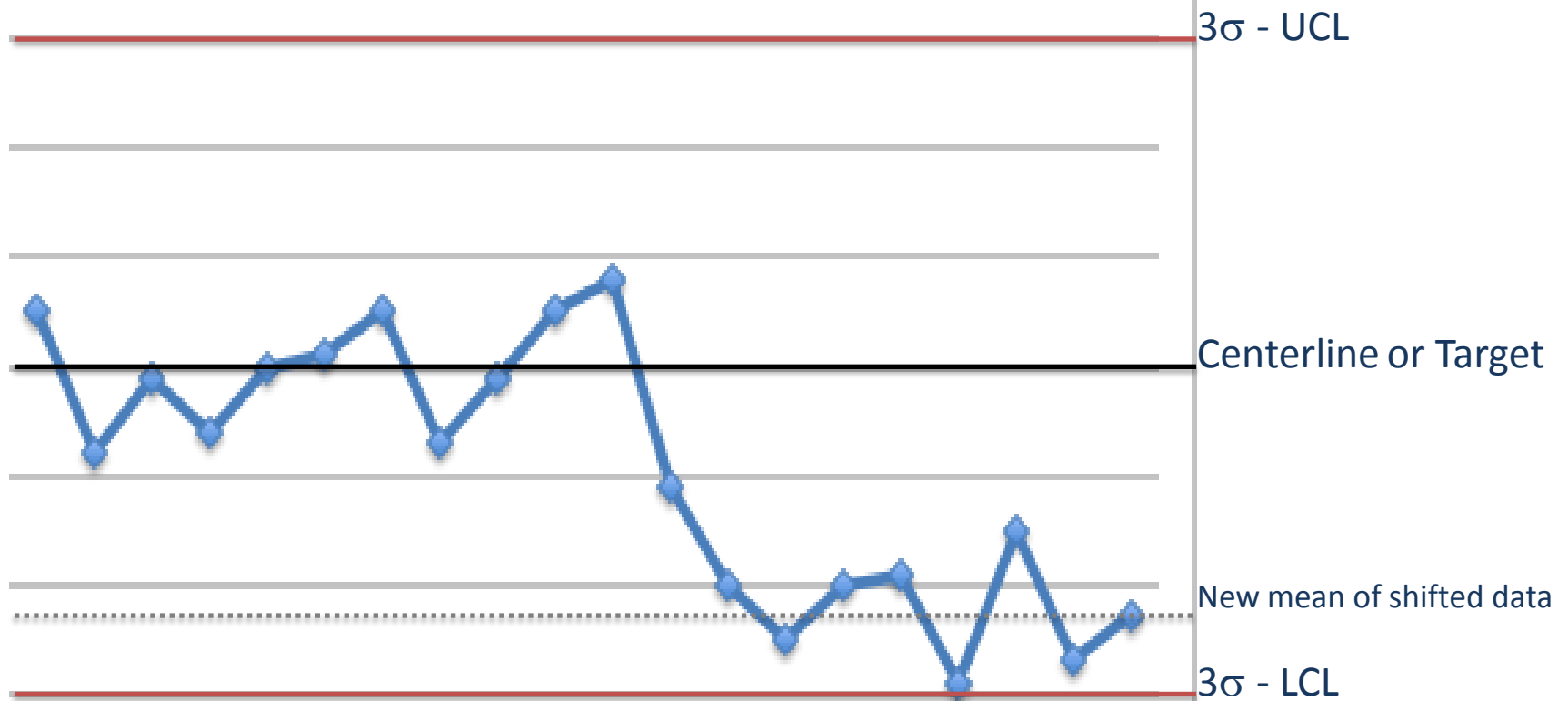
Rule 7: 8 or more successive numbers that avoid $\mu \pm 1\sigma$ zone.

Rule 8: 15 successive points fall into $\mu \pm 1\sigma$ zone only, to either side of the centerline or target.



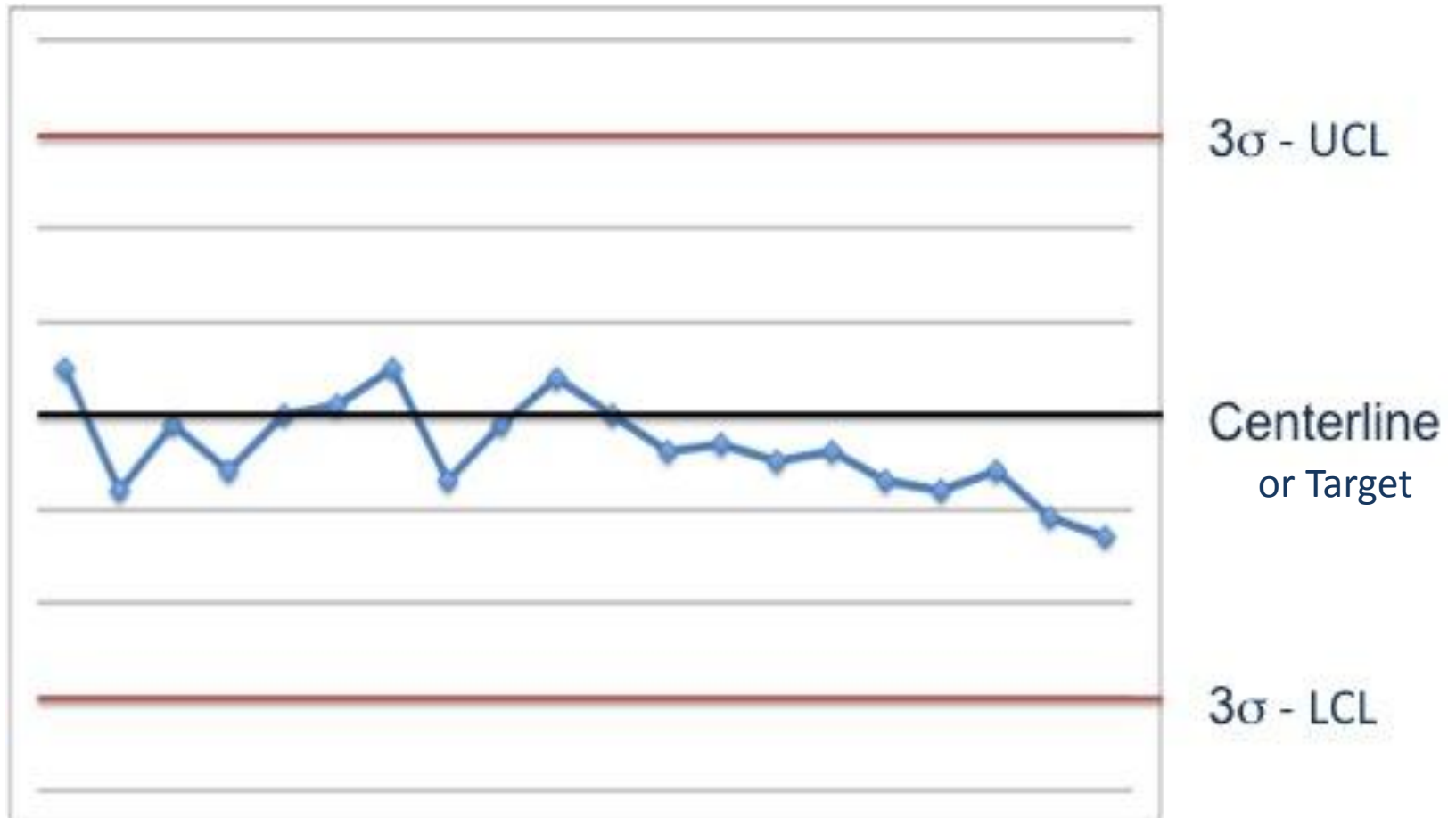
Process Changes - Shift

Shift – When the data starts to center around a different mean or center line.



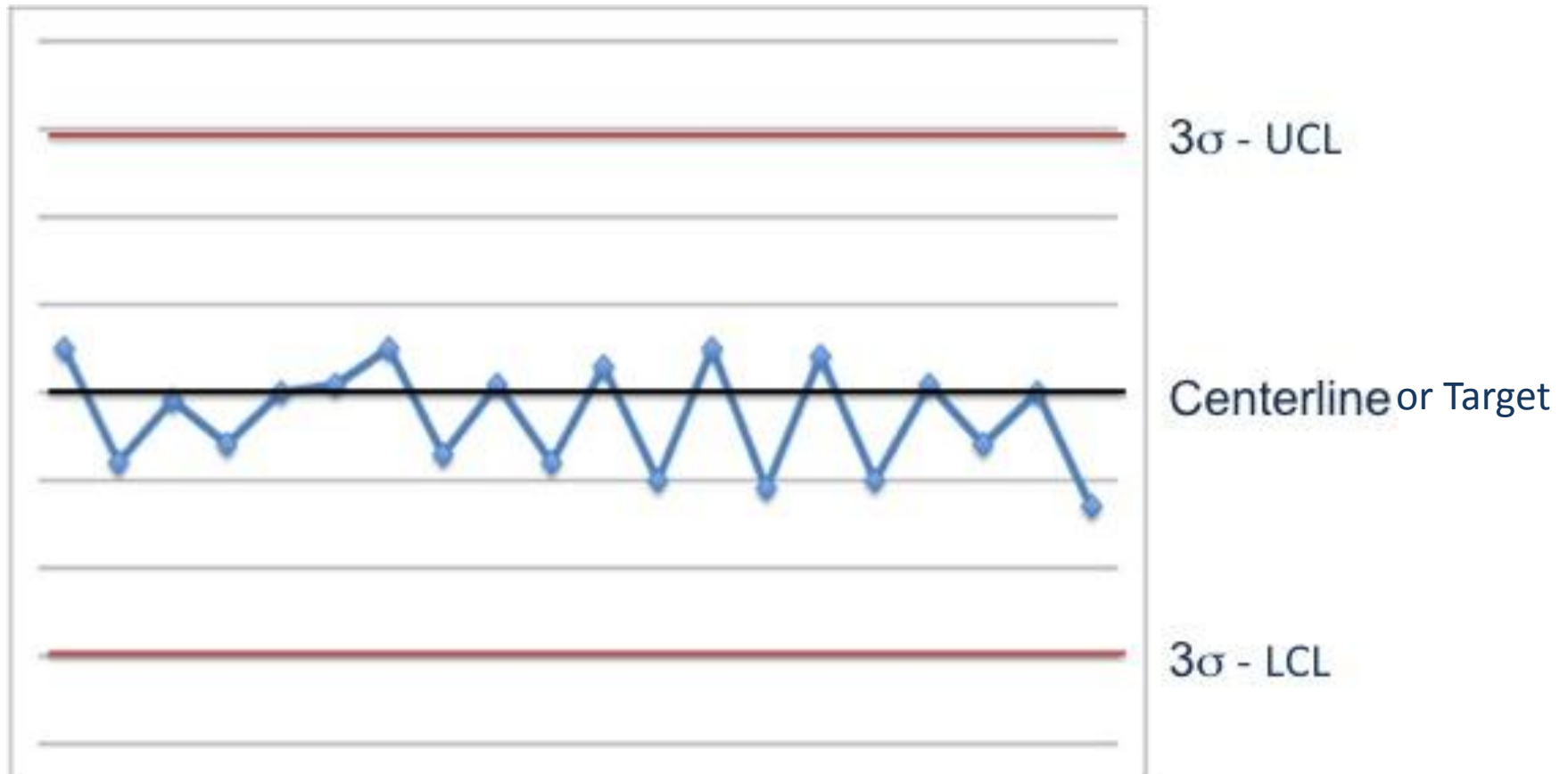
Process Changes - Trend

Trend – When the process mean begins to gradually move in one direction.



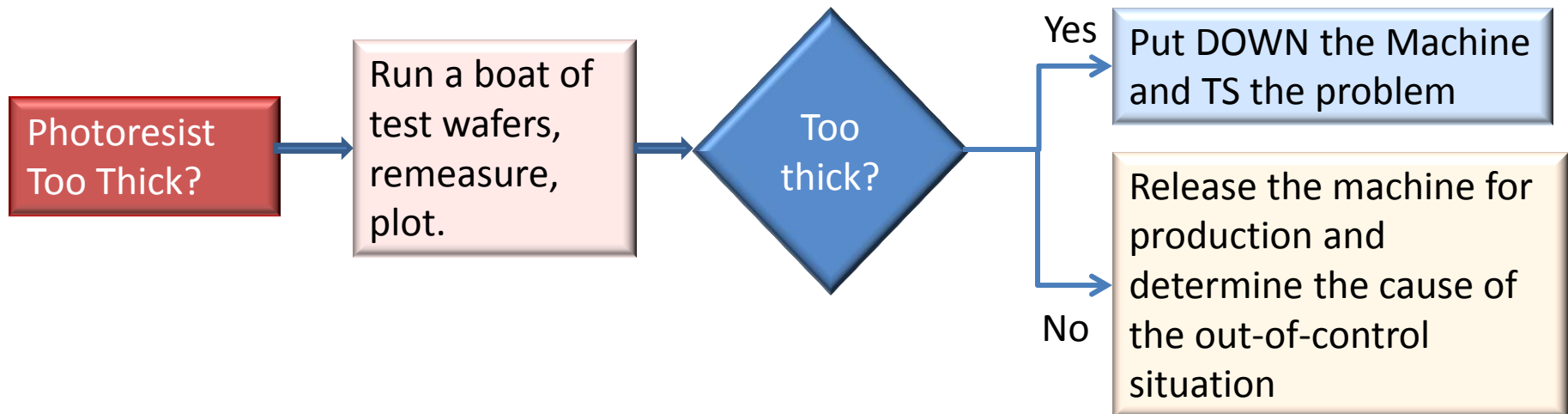
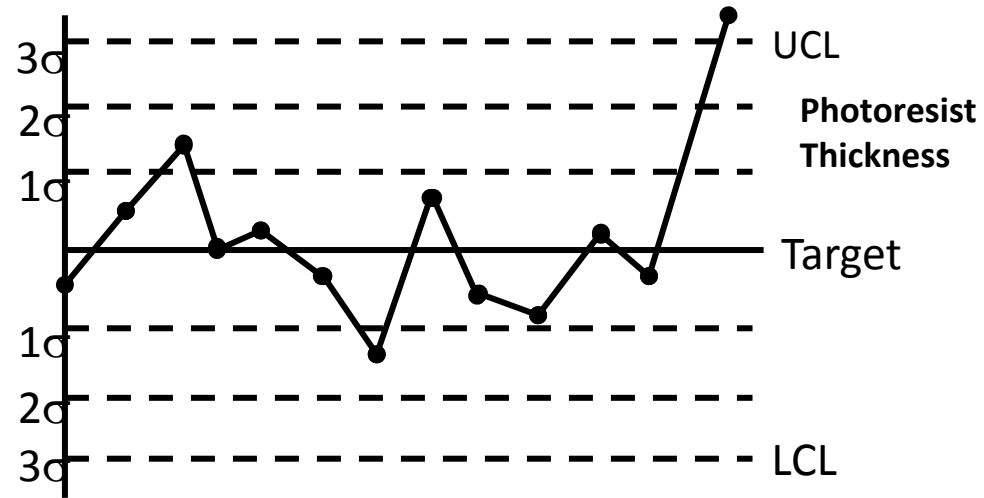
Process Changes - Cycle

Cycle – When the data begins to increase or decrease in a cyclical or repetitive manner.

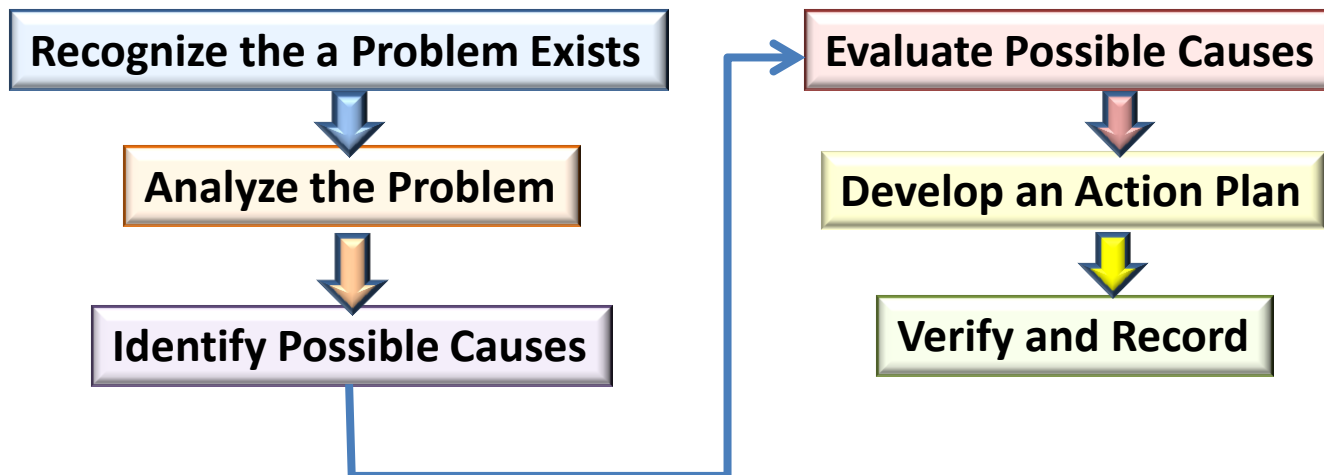
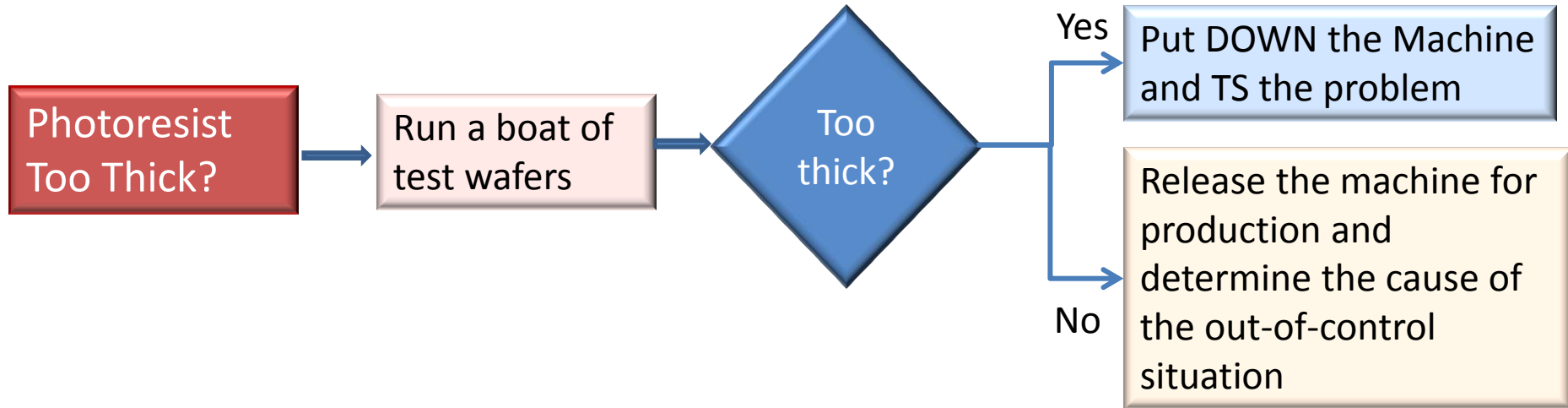


Out of Control Action Plan - OCAP

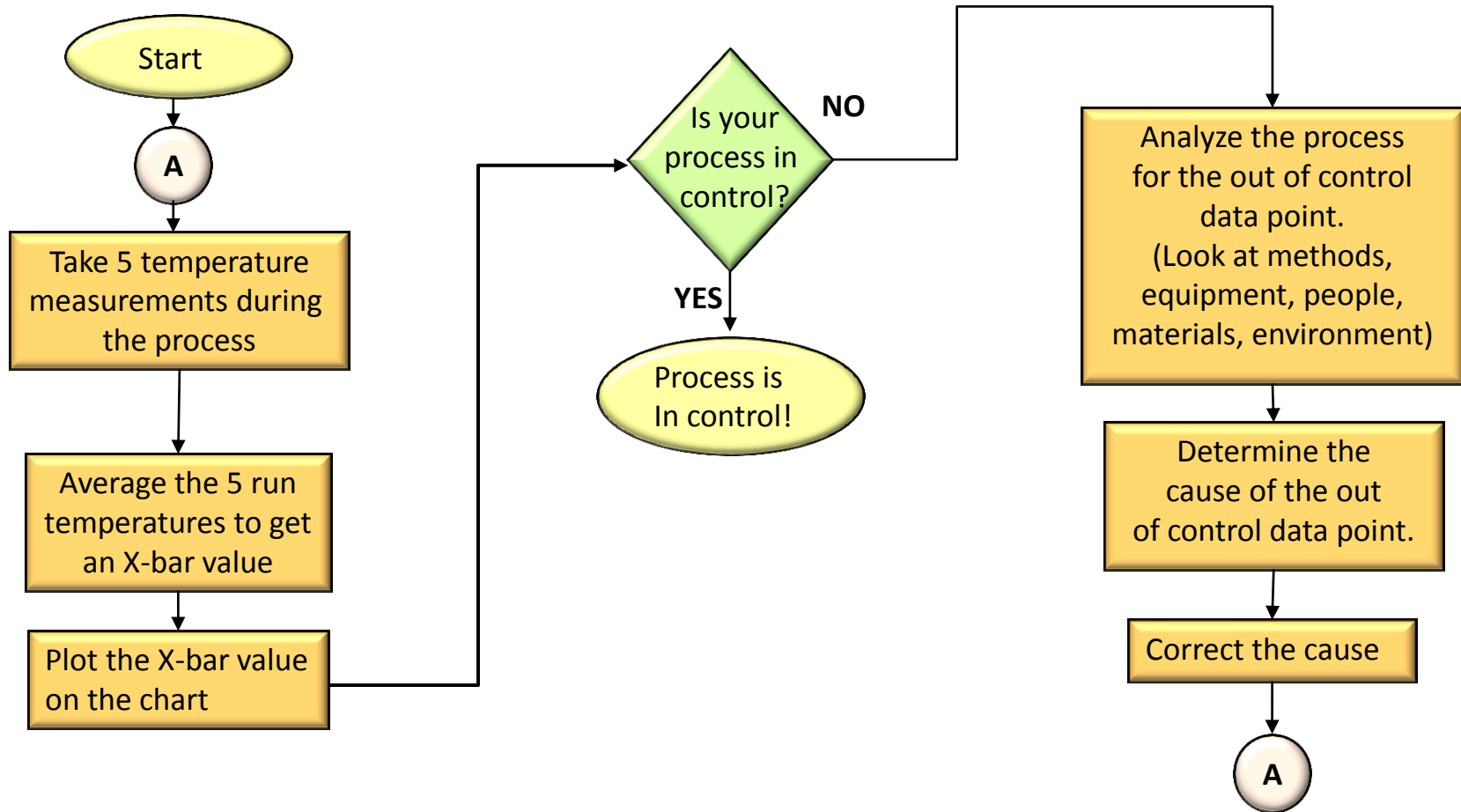
You are a technician in the photolithography aisle of a local MEMS fabrication facility. After randomly testing several wafers from the last processing batch and plotting the data on a control chart, you identify an out-of-control situation with resist thickness.



Out of Control Action Plan - OOCAP



Data Collection/Analysis Plan



Control Limits are NOT Specification Limits

- Control Chart Centerline
 - Derived from real-time process data
- Control Limits
 - Derived from real-time process data
- Specification Limits (Spec Limits)
 - Boundaries that a product is acceptable or *not* acceptable
- Just because a process is in statistical control does not mean it is always within spec and vice versa
- SPC has to do with process predictability
- Process Specification Limits have to do with the process capability
- General Rule: Do not put Specification Limits in a control chart!

EXAMPLE – SiO₂ Growth

- Silicon Dioxide Growth for a Sacrificial Layer on a MEMS device
- Specification states that the Average Run Temperature (\bar{X}) should be $1000^{\circ}\text{C} \pm 10^{\circ}\text{C}$

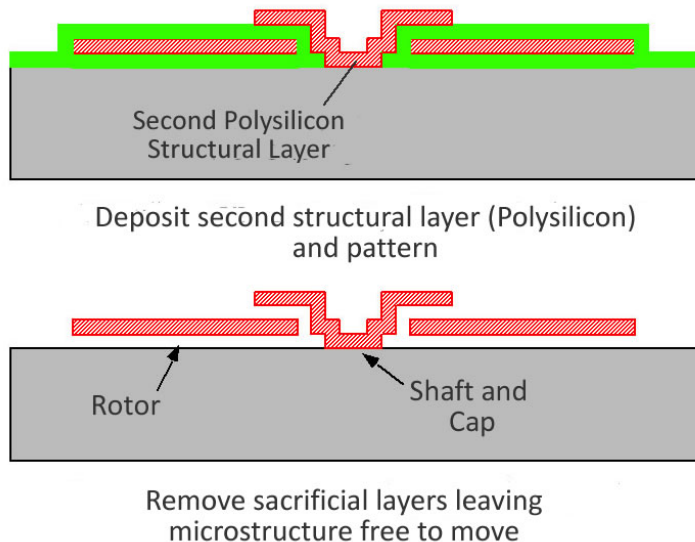


Image courtesy of UNM MTTC



\bar{X} -Chart for SiO₂ Growth

$$\sigma = 3.77 \text{ } ^\circ\text{C}$$

$$\mu + 3\sigma = 1004 + (3 \cdot 3.77) = 1015 \text{ } ^\circ\text{C}$$

$$\mu - 3\sigma = 1004 - (3 \cdot 3.77) = 993 \text{ } ^\circ\text{C}$$

UCL

$$\mu + 3\sigma = 1015 \text{ } ^\circ\text{C}$$

Target = 1004°C

LCL

$$\mu - 3\sigma = 993 \text{ } ^\circ\text{C}$$



\bar{X} -Chart for SiO₂ Growth

Management has determined that this process should be monitored for only the following 4 Shewhart Rules:

Rule 1: A single point outside the $\mu \pm 3\sigma$ zone.

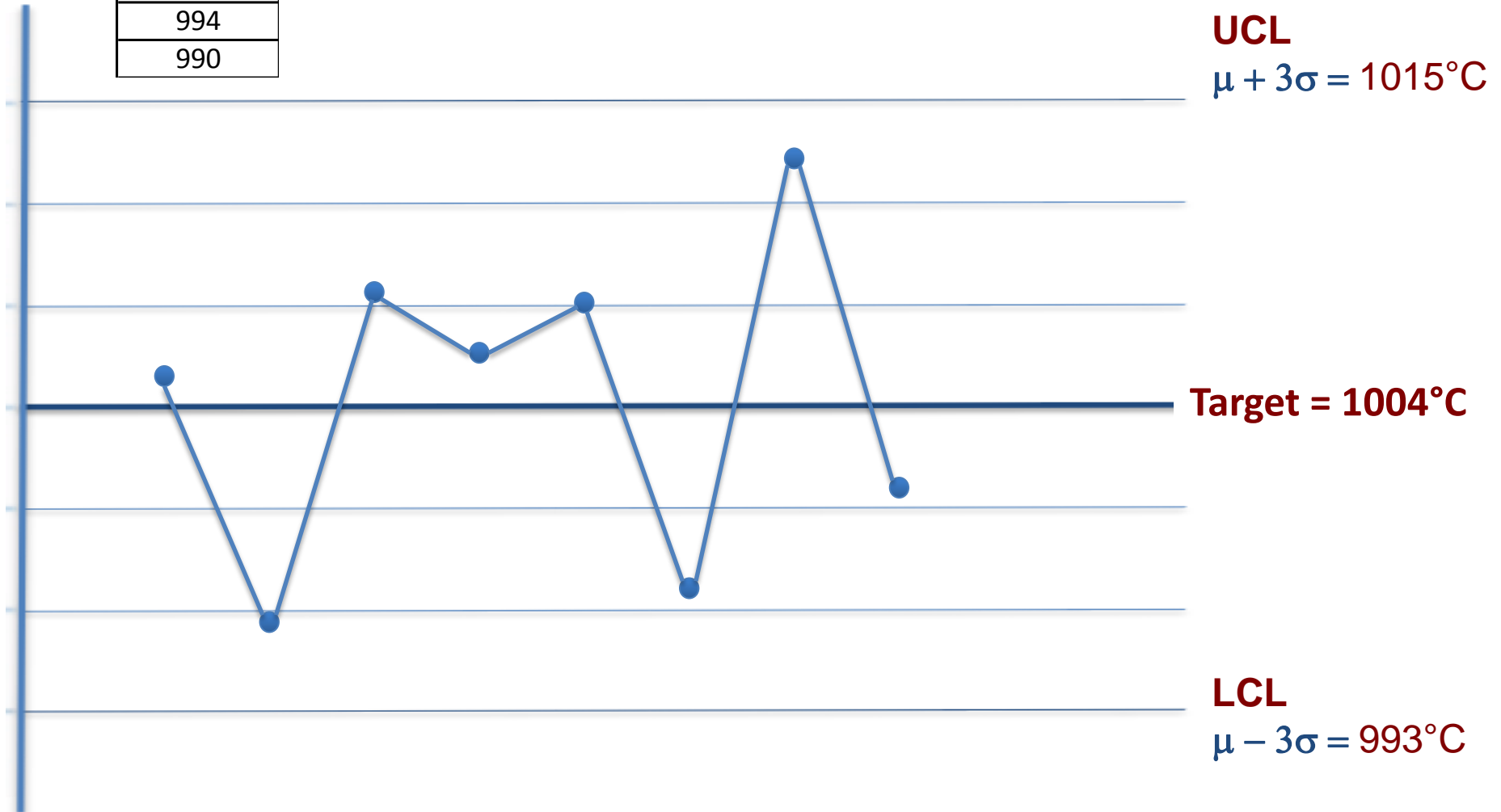
Rule 2: Two out of three successive points outside $\mu \pm 2\sigma$ zone.

Rule 4: 8 or more successive numbers either strictly above or strictly below the mean.

Rule 5: 6 or more successive numbers showing a continuous increase or continuous decrease.

\bar{X} -Chart for SiO₂ Growth

Run #
992
989
987
994
990



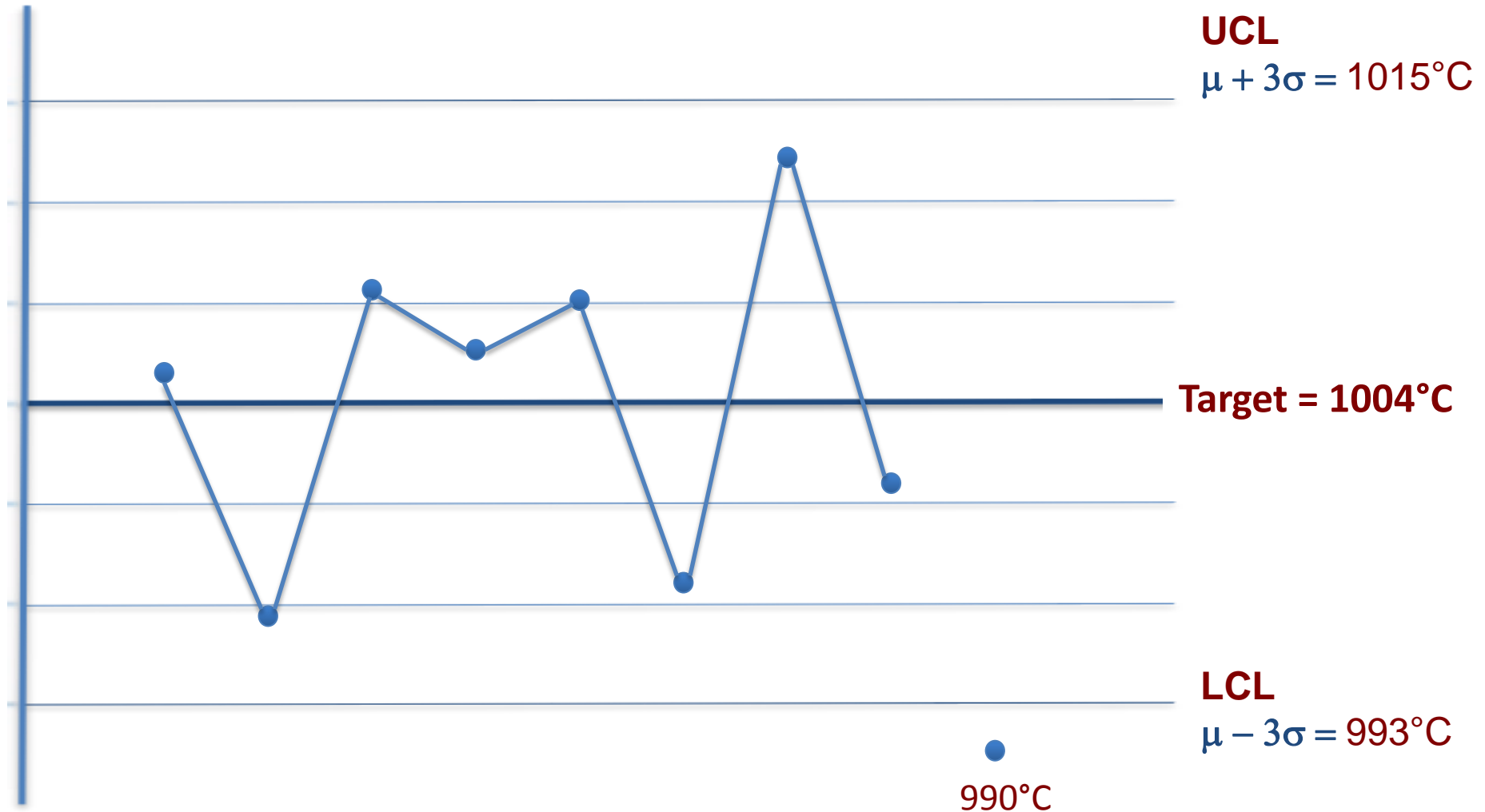
\bar{X} -Chart for SiO₂ Growth

Rule 1: A single point outside the $\mu \pm 3\sigma$ zone.

Rule 2: Two out of three successive points outside $\mu \pm 2\sigma$ zone.

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Rule 5: 6 or more successive numbers showing a continuous increase or continuous decrease.



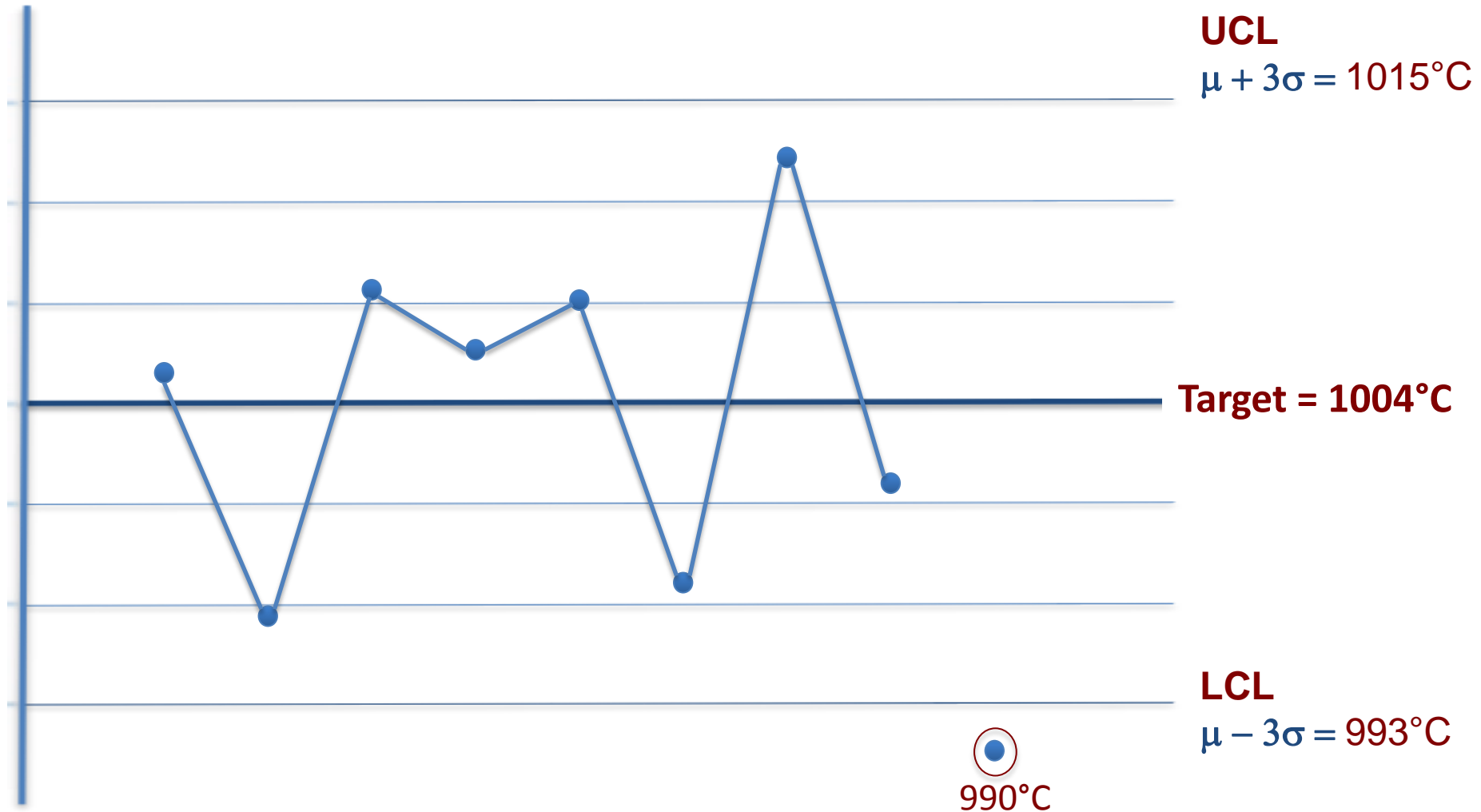
\bar{X} -Chart for SiO₂ Growth

Rule 1: A single point outside the $\mu \pm 3\sigma$ zone.

Rule 2: Two out of three successive points outside $\mu \pm 2\sigma$ zone.

Rule 4: 8 or more successive numbers either strictly above or strictly below the mean.

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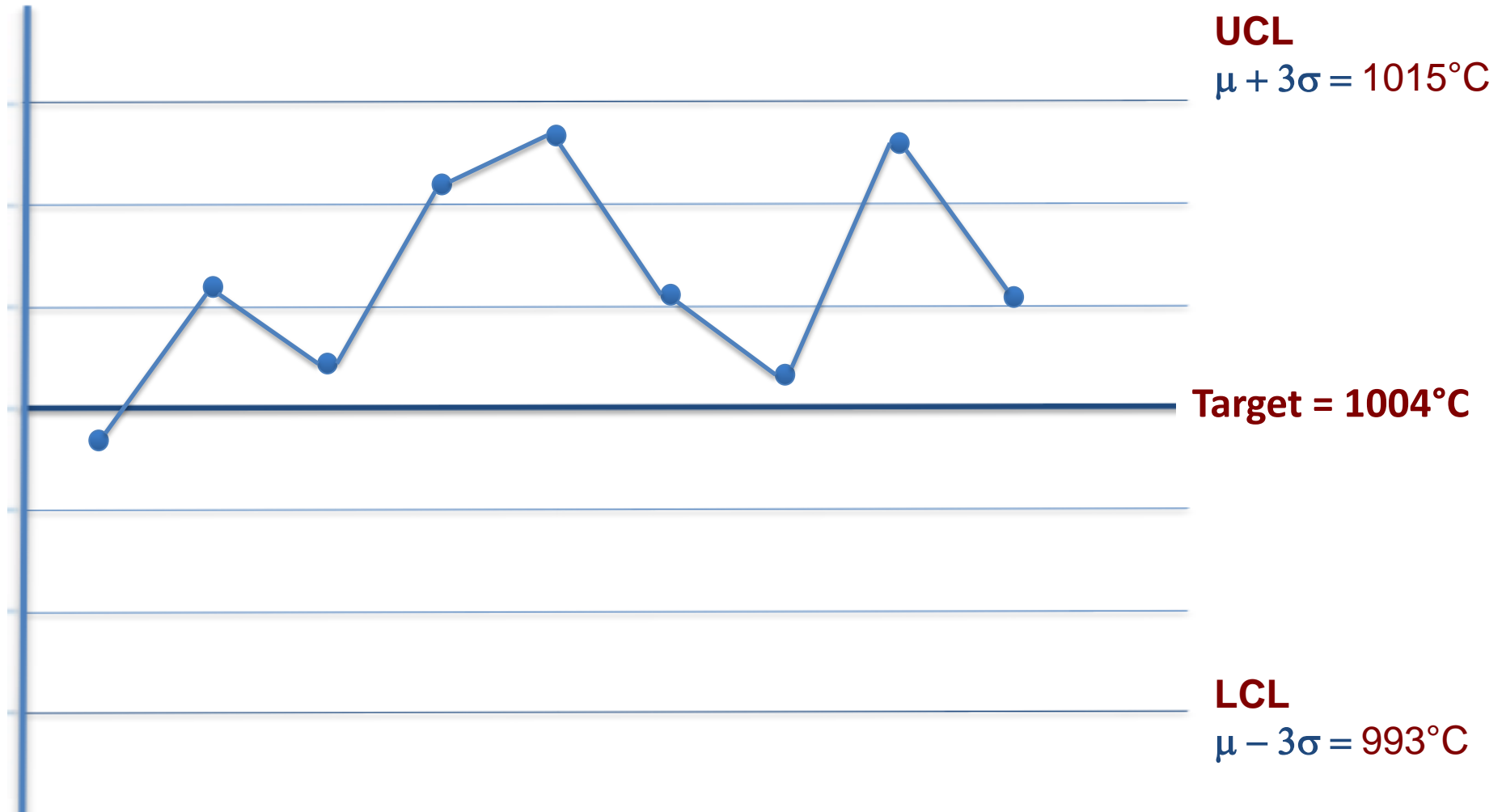
\bar{X} -Chart for SiO₂ Growth

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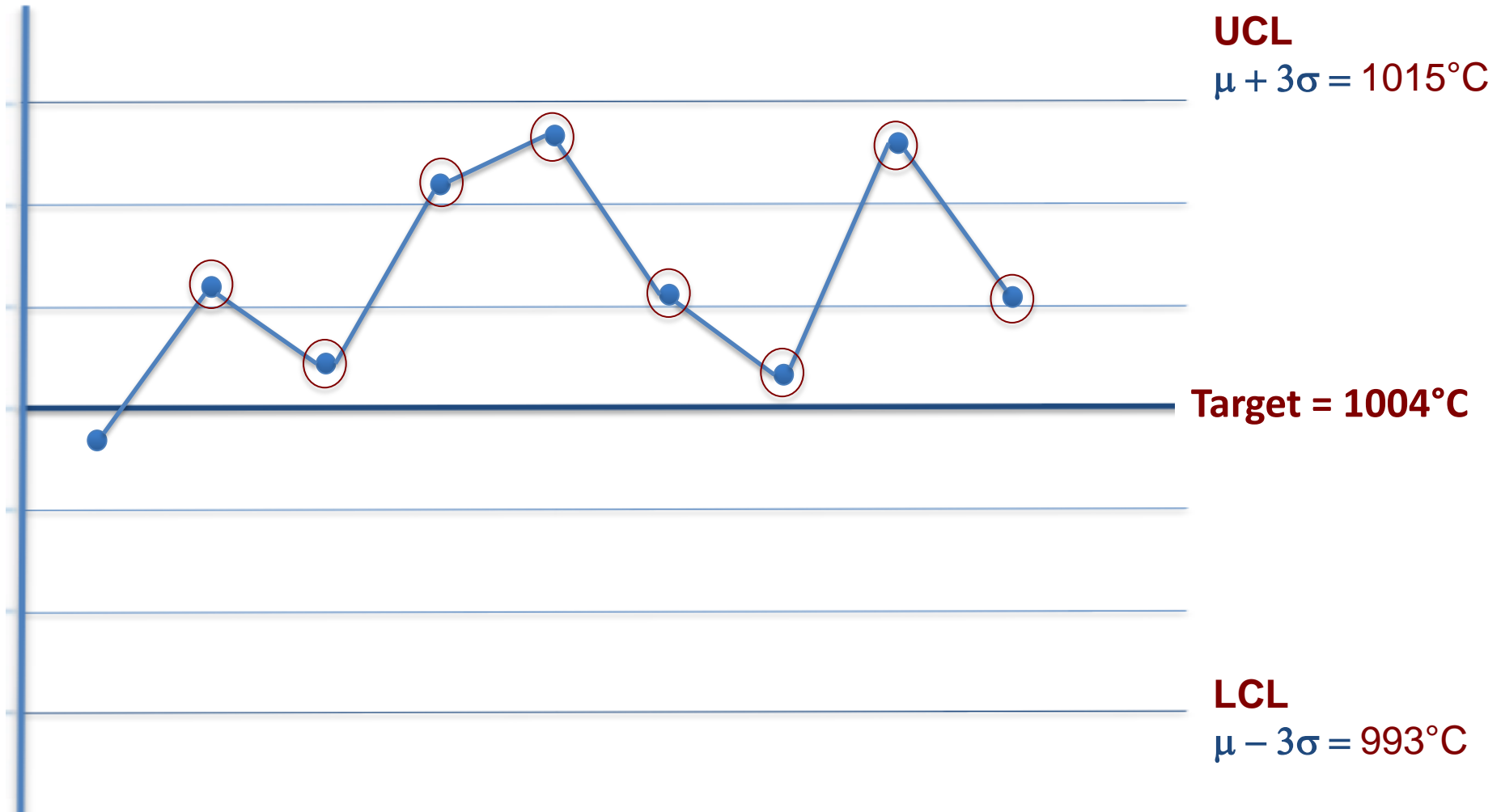
\bar{X} -Chart for SiO₂ Growth

Rule 1: A single point outside the $\mu \pm 3\sigma$ zone.

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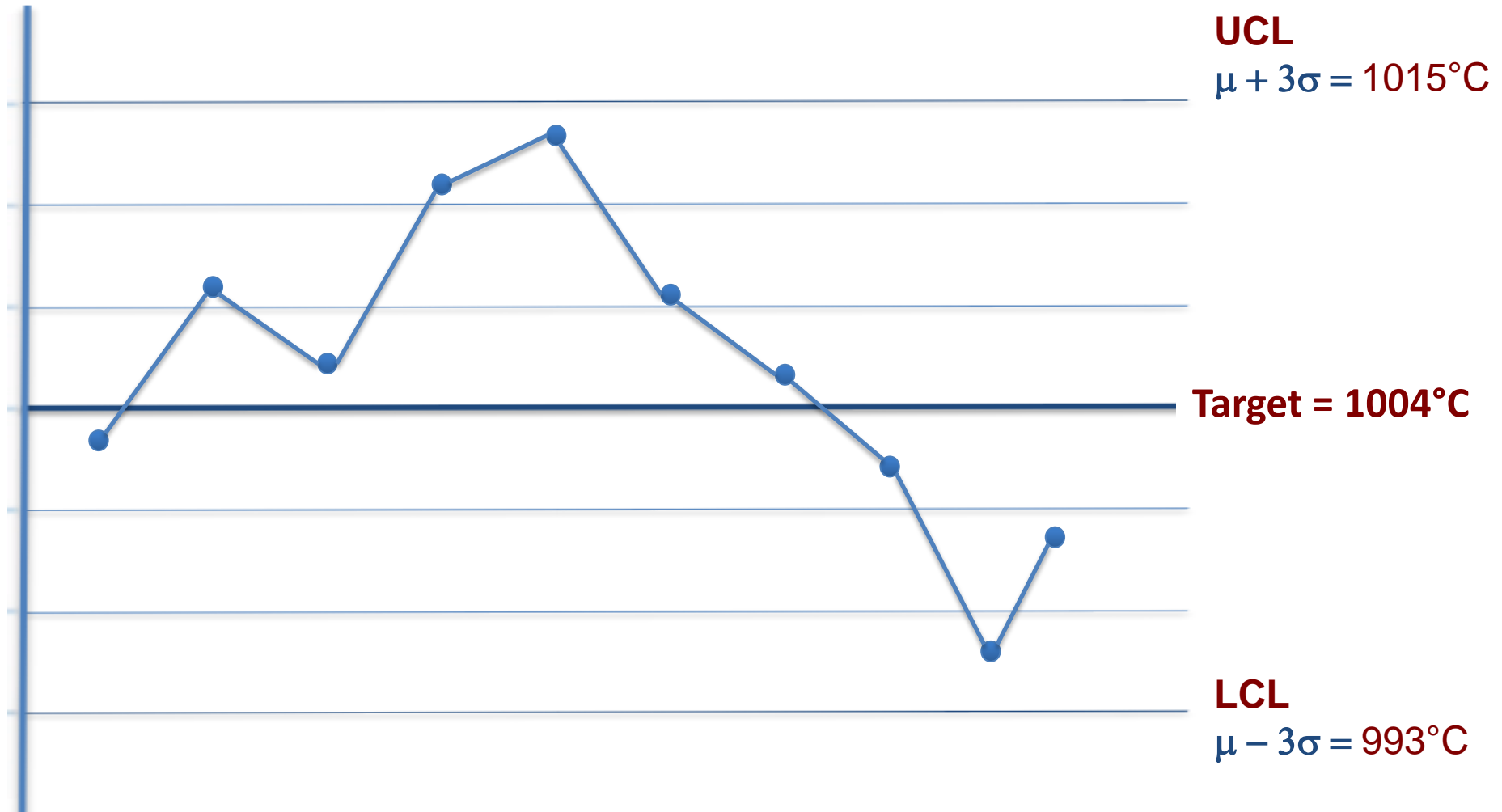
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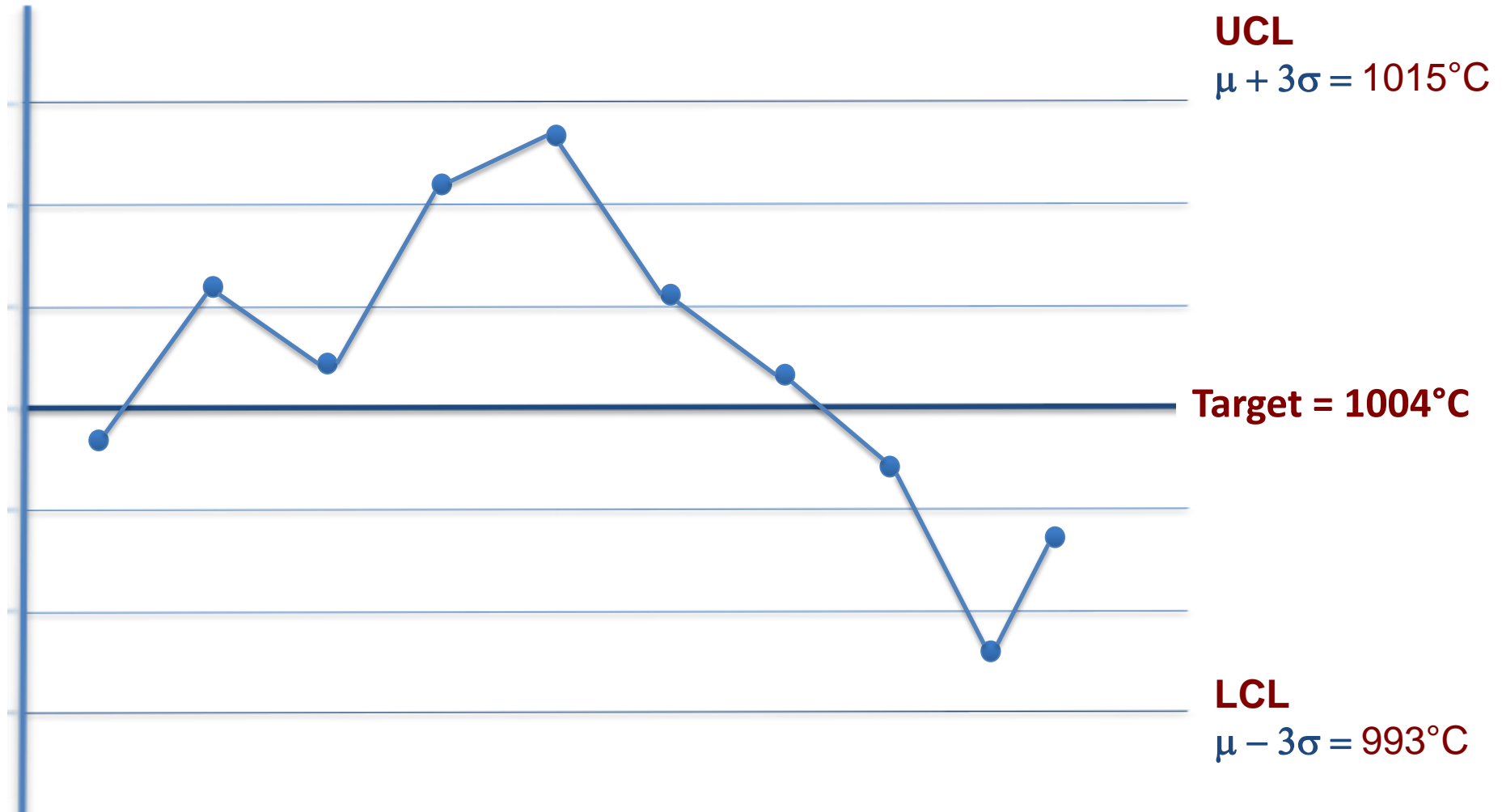
\bar{X} -Chart for SiO₂ Growth

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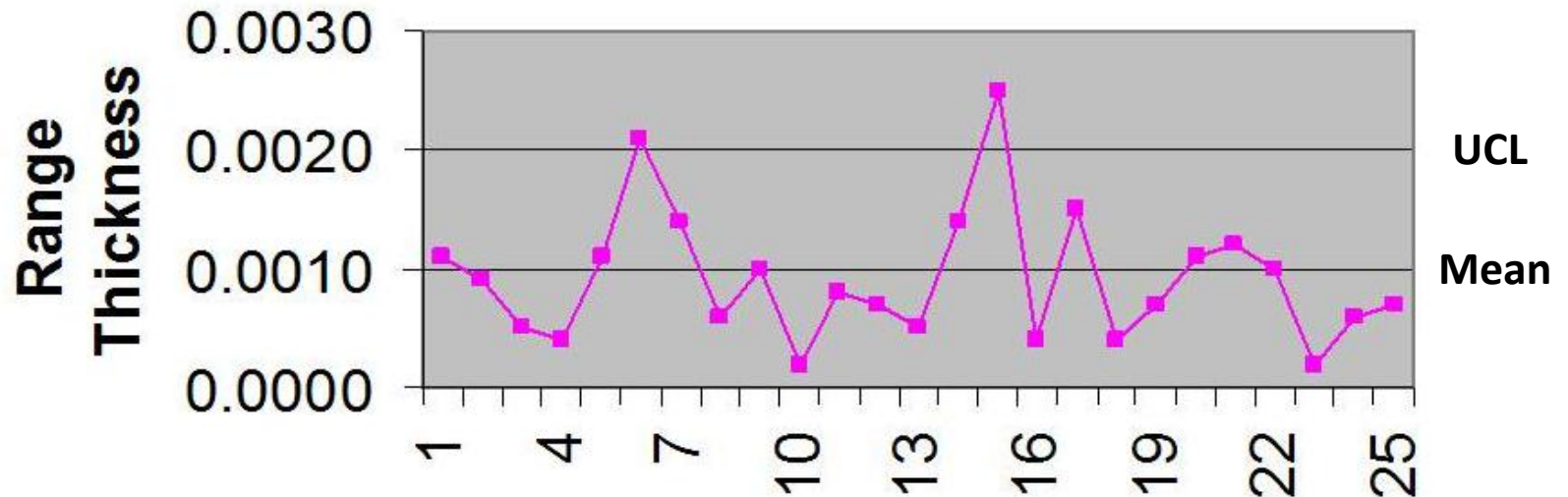
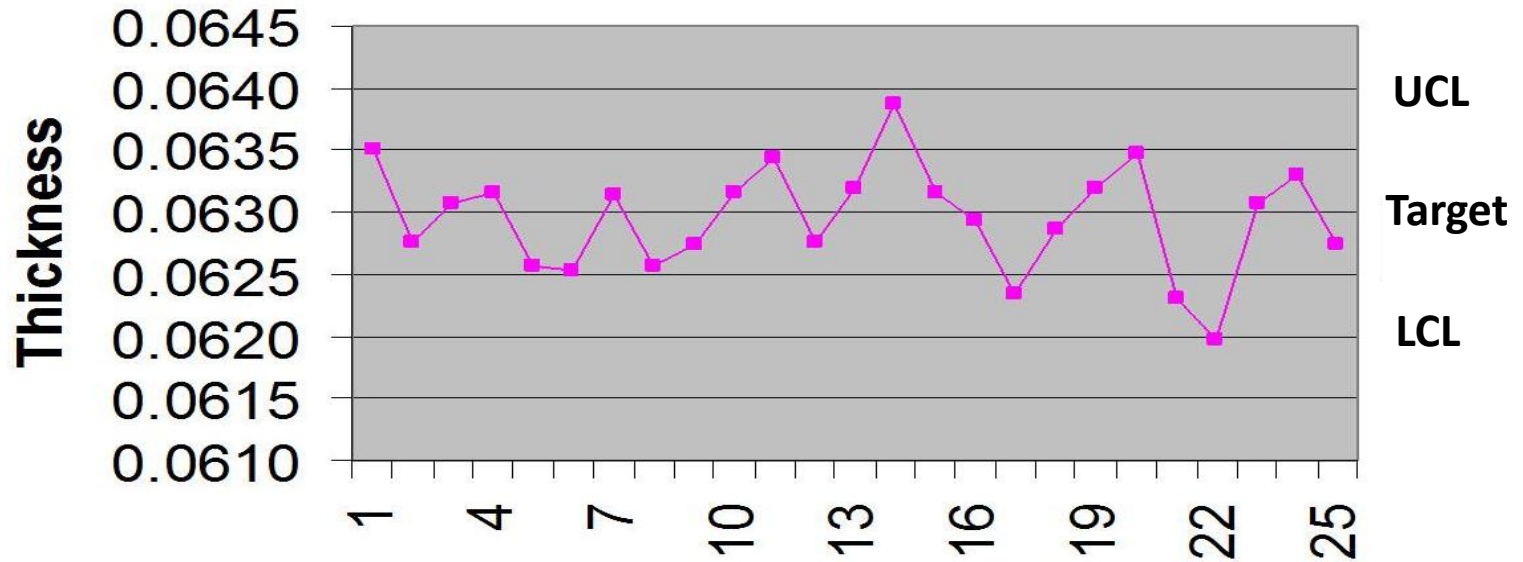
Rule 5: 6 or more successive numbers showing a continuous increase or continuous decrease.



Other types of Charts

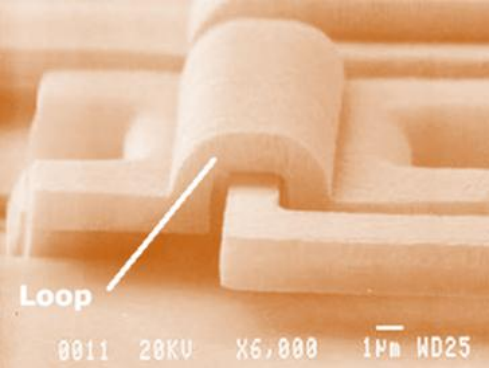
- \bar{X} and R chart
- \bar{X} and s chart
- p-Chart and np-chart (defectives)
- U and c charts (defects)
- Individuals Chart
- Exponentially Weighted Moving Average (EWMA) Chart

X-bar R charts for Film Thickness

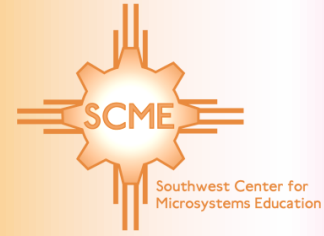


Summary

- SPC is a statistical scientific method that provides valuable information about a process
- They type of variation (common and special cause) should be understood and controlled.
- Statistical Concepts used in SPC
 - Sample median
 - Sample mean – μ , \bar{X} , $\bar{\bar{X}}$
 - Sample range - R
 - Sample variance – σ^2
 - Sample standard deviation – σ
- Most process data follows a Normal Distribution
- Shewhart or Western Electric Rules can be used to determine if a process goes out of control



Thank You For Joining Us

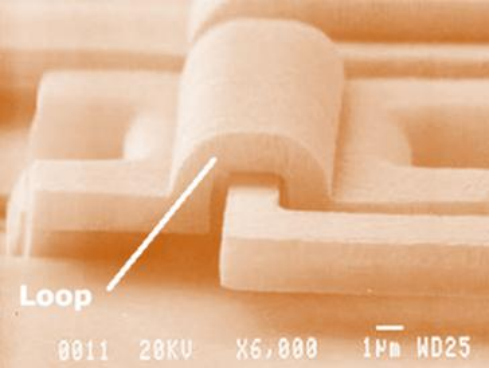


Barb Lopez
botero@unm.edu

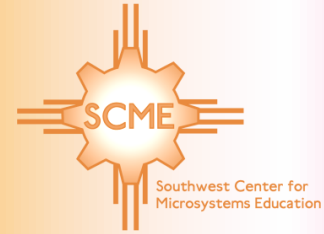


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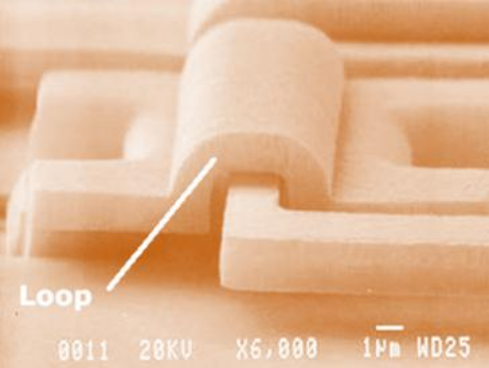


How Can We Serve You Better?

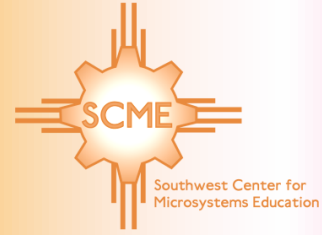


Please take 1 minute to provide your
feedback and suggestions

<https://www.surveymonkey.com/s/J9TVRSZ>

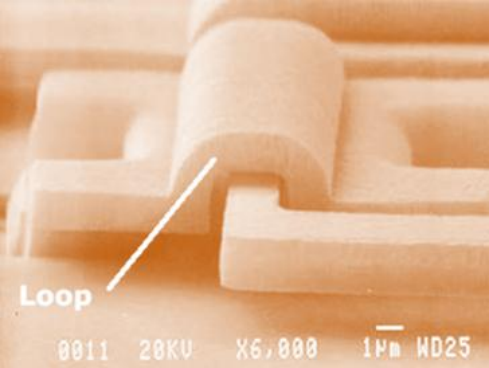


Webinar Resources

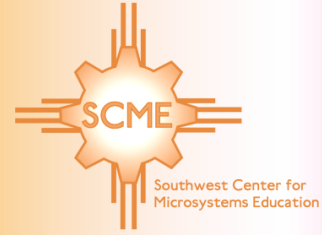


To access this webinar recording, slides, and handout, please visit

www.scme-nm.org



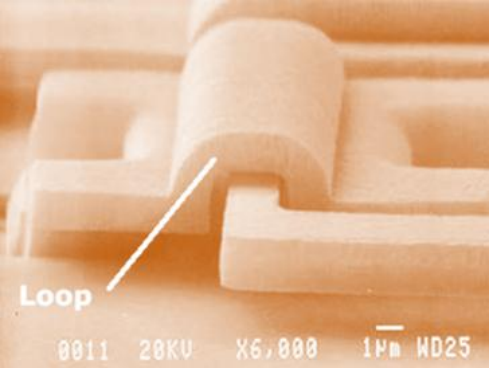
SCME Upcoming Webinars



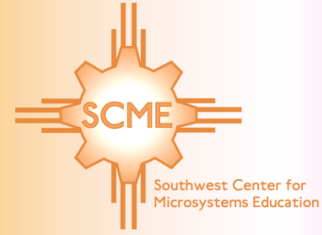
February 28, 2013: Design of Experiments for Technicians

March 28, 2013: Problem-solving Tools Applied to Microfabrication

All Webinars on Thursday @ 1 PM ET



It was Fun!



Thank you for attending this
SCME Webinar

Problem Solving for
Technicians